

MOS INTEGRATED CIRCUIT

μ PD784035Y,784036Y,784037Y,784038Y

16-/8-BIT SINGLE-CHIP MICROCONTROLLERS

DESCRIPTION

The μ PD784038Y is based on the μ PD784038 with an I²C bus control function added, and is ideal for audio-visual applications.

One-time PROM and EPROM versions, such as the μ PD78P4038Y, that can operate in the same voltage range as mask ROM versions, and various development tools are provided.

The functions are explained in detail in the following User's Manual. Be sure to read this manual when designing your system.

 μ PD784038, 784038Y Subseries User's Manual - Hardware: U11316E 78K/IV Series User's Manual - Instruction: U10905E

FEATURES

- 78K/IV Series
- Pin-compatible with μPD78234 Subseries, μPD784026 Subseries, and μPD784038 Subseries
- Higher internal memory capacity than μPD78234
 Subseries and μPD784026 Subseries
- Minimum instruction execution time: 125 ns (@ 32-MHz operation)
- I/O ports: 64
- Serial interface: 3 channels
 UART/IOE (3-wire serial I/O): 2 channels
 CSI (3-wire serial I/O, 2-wire serial I/O, I²C bus):
 1 channel

- Timer/counter 16-bit timer/counter × 3 units 16-bit timer × 1 unit
- PWM output: 2 outputs
- Standby function
 HALT/STOP/IDLE mode
- · Clock division function
- Watchdog timer: 1 channel
- Clock output function
 Selectable from fclk, fclk/2, fclk/4, fclk/8, and fclk/16
- A/D converter: 8-bit resolution × 8 channels
 D/A converter: 8-bit resolution × 2 channels
- Supply voltage: VDD = 2.7 to 5.5 V

APPLICATION FIELDS

Cellular phones, cordless phones, audio-visual systems, etc.

Unless contextually excluded, references in this document to the μ PD784038Y mean μ PD784035Y, μ PD784036Y, and μ PD784037Y.

The information in this document is subject to change without notice.



ORDERING INFORMATION

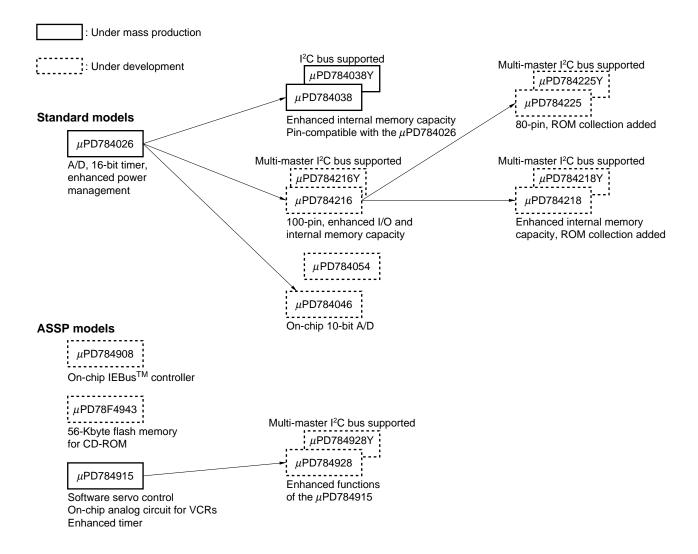
_	Part Number	Package	Internal ROM (Bytes)	Internal RAM (Bytes)
	μPD784035YGC-xx-3B9	80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick	x) 48 K	2048
*	μ PD784035YGC- \times \times -8BT	80-pin plastic QFP (14 \times 14 mm, 1.4-mm thick	3) 48 K	2048
	$\mu PD784035YGK\text{-}x\!\!\times\!\!\!-BE9^{\mathbf{Note}}$	80-pin plastic TQFP (fine pitch) (12 \times 12 mm)	48 K	2048
	μPD784036YGC-×××-3B9	80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick	() 64 K	2048
*	μ PD784036YGC- \times \times -8BT	80-pin plastic QFP (14 \times 14 mm, 1.4-mm thick	() 64 K	2048
	$\mu PD784036YGK\text{-}x\!\!\times\!\!\!-\!\!BE9^{\mathbf{Note}}$	80-pin plastic TQFP (fine pitch) (12 \times 12 mm)	64 K	2048
	μ PD784037YGC- \times \times -3B9	80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick	s) 96 K	3584
*	μ PD784037YGC- \times \times -8BT	80-pin plastic QFP (14 \times 14 mm, 1.4-mm thick	s) 96 K	3584
	μ PD784037YGK- $\times\!\!\times\!\!$ -BE9	80-pin plastic TQFP (fine pitch) (12 \times 12 mm)	96 K	3584
	μ PD784038YGC- \times \times -3B9	80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick	() 128 K	4352
*	μ PD784038YGC- \times \times -8BT	80-pin plastic QFP (14 \times 14 mm, 1.4-mm thick	:) 128 K	4352
	μ PD784038YGK- $\times\!\!\times\!\!$ -BE9	80-pin plastic TQFP (fine pitch) (12 \times 12 mm)	128 K	4352

Note Under development

Remark xxx indicates the ROM code suffix.



78K/IV Series Product Development





FUNCTIONS

	Part Number	μPD784035Y	μPD784036Y	μPD784037Y	μPD784038Y	
Item						
Number of basic in (mnemonics)	instructions	113				
General-purpose	register	8 bits × 16 registe	ers \times 8 banks, or 16 bits \times	8 registers × 8 banks	(memory mapping)	
Minimum instructi time	on execution	125 ns/250 ns/50	0 ns/1000 ns (@ 32-MHz	operation)		
Internal memory	ROM	48 KBytes	64 KBytes	96 KBytes	128 KBytes	
	RAM	2048 Bytes		3584 Bytes	4352 Bytes	
Memory space		1 MByte with pro	gram and data spaces con	nbined		
I/O port	Total	64				
	Input	8				
	I/O	56				
Pins with ancillary	Pins with pull- up resistor	54				
functionNote	LEDs direct drive output	24				
	Transistor direct drive	8				
Real-time output	port	4 bits × 2 or 8 bit	s × 1			
Timer/counter		Timer/counter 0: (16 bits)	$ \begin{array}{l} \text{Timer register} \times 1 \\ \text{Capture register} \times 1 \\ \text{Compare register} \times 2 \end{array} $	Pulse output • Toggle out • PWM/PPG • One-shot p	put output	
		Timer/counter 1: (8/16 bits)	Timer register × 1 Capture register × 1 Capture/compare register Compare register × 1		coutput (4 bits × 2)	
		Timer/counter 2: (8/16 bits)	Timer register × 1 Capture register × 1 Capture/compare register Compare register × 1	Pulse output • Toggle out × 1 • PWM/PPG	put	
		Timer 3: (8/16 bits)	Timer register × 1 Compare register × 1			
PWM output		12-bit resolution × 2 channels				
Serial interface		UART/IOE (3-wire serial I/O) : 2 channels (on-chip baud rate generator) CSI (3-wire serial I/O, 2-wire serial I/O, I ² C bus) : 1 channel				
A/D converter		8-bit resolution ×				
D/A converter		8-bit resolution × 2 channels				
Clock output		Selectable from f	clk, fclk/2, fclk/4, fclk/8, fcli	k/16 (can also be used	as 1-bit output port)	
Watchdog timer		1 channel				
Standby		HALT/STOP/IDLE mode				
Interrupt	Hardware source	24 (internal: 17, 6	external: 7 (variable sampli	ing clock input: 1))		
-	Software source	· · · · · · · · · · · · · · · · · · ·	BRKCS instruction, operar			
	Non-maskable					
	Maskable	Internal: 16, exte				
		 4 programmable priority levels 3 processing styles: vectored interrupt/macro service/context switching 				
Supply voltage		V _{DD} = 2.7 to 5.5 \				
Package		80-pin plastic QF	P (14 \times 14 mm, 2.7-mm th P (14 \times 14 mm, 1.4-mm th	•		
		80-pin plastic TQFP (fine pitch) (12 × 12 mm)				

 $\textbf{Note} \ \ \text{The pins with ancillary function are included in the I/O pins.}$

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1. DIFFERENCES AMONG MODELS IN μ PD784038Y SUBSERIES

The only difference among the μ PD784035Y, 784036Y, 784037Y, and 784038Y lies in the internal memory capacity.

The μ PD78P4038Y is provided with a 128-KB one-time PROM or EPROM instead of the mask ROM of the above models. These differences are summarized in Table 1-1.

Table 1-1. Differences among Models in μ PD784038Y Subseries

Part Number Item	μPD784031Y	μPD784035Y	μPD784036Y	μPD784037Y	μPD784038Y	μPD78P4038Y
Internal ROM	Not available	48 KBytes (mask ROM)	64 KBytes (mask ROM)	96 KBytes (mask ROM)	128 KBytes (mask ROM)	128 KBytes (one-time PROM or EPROM)
Internal RAM	2048 Bytes			3584 Bytes	4352 Bytes	
Package	80-pin plastic QFP (14 × 14 mm, 2.7-mm thick) 80-pin plastic QFP (14 × 14 mm, 1.4-mm thick) 80-pin plastic TQFP (fine pitch) (12 × 12 mm) 80-pin plastic TQFP (fine pitch) (12 × 12 mm)					



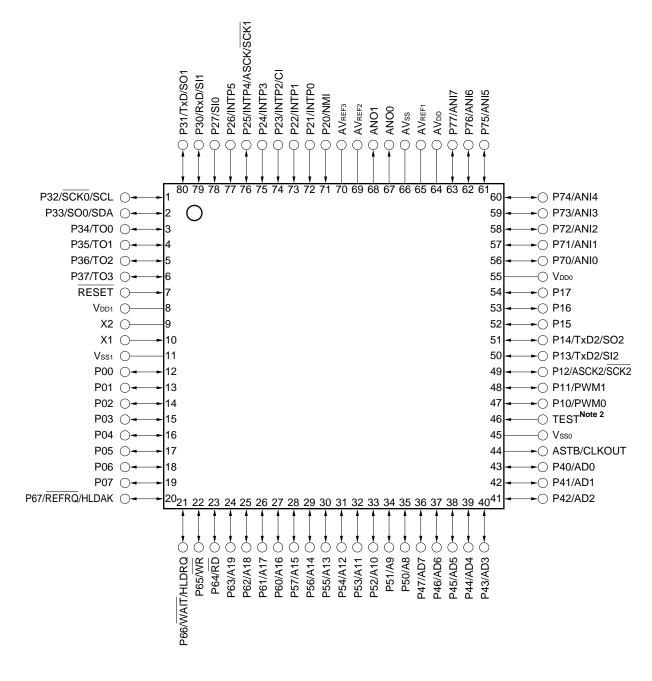
2. MAJOR DIFFERENCES FROM μ PD784026 SUBSERIES AND μ PD78234 SUBSERIES

Series Name		μPD784038Y Subseries	μPD784026 Subseries	μPD78234 Subseries
Item		μPD784038 Subseries		
Number of basic instructions (mnemonics)		113		65
Minimum instruct	ion execution time	125 ns (@ 32-MHz operation)	160 ns (@ 25-MHz operation)	333 ns (@ 12-MHz operation)
Memory space (p	orogram/data)	1 MByte combined		64 KBytes/1 MByte
Timer/counter		16-bit timer/counter × 1 8-/16-bit timer/counter × 2 8-/16-bit timer × 1		16-bit timer/counter × 1 8-bit timer/counter × 2 8-bit timer × 1
Clock output fund	ction	Provided		None
Watchdog timer		Provided		None
Serial interface		UART/IOE (3-wire serial I/O) × 2 channels CSI (3-wire serial I/O, SBI) 2-wire serial I/O, I ² C bus ^{Note}) × 1 channel		UART × 1 channel CSI (3-wire serial I/O, SBI) × 1 channel
Interrupt	Context switching	Provided		None
	Priority	4 levels		2 levels
Standby function		HALT/STOP/IDLE modes		HALT/STOP modes
Operating clock		Selectable from fxx/2, fxx/4, fxx/8, and fxx/16		Fixed to fxx/2
Pin function	MODE pin	None		Specifies ROM-less mode (always high level with μPD78233 and 78237)
	TEST pin	Device test pin Usually, low level		None
Package		80-pin plastic QFP (14 × 14 mm, 2.7-mm thick) 80-pin plastic QFP (14 × 14 mm, 1.4-mm thick) 80-pin plastic TQFP (fine pitch) (12 × 12 mm) 80-pin ceramic WQFN (14 × 14 mm): μPD78P4038Y and 78P4038 only	80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick) 80-pin plastic TQFP (fine pitch) (12 \times 12 mm): μ PD784021 only 80-pin ceramic WQFN (14 \times 14 mm): μ PD78P4026 only	80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick) 94-pin plastic QFP (20 \times 20 mm) 84-pin plastic QFJ (1150 \times 1150 mil) 94-pin ceramic WQFN (20 \times 20 mm): μ PD78P238 only

Note μ PD784038Y Subseries only

3. PIN CONFIGURATION (Top View)

- 80-pin plastic QFP (14 × 14 mm, 2.7-mm thick)
 μPD784035YGC-xxx-3B9, 784036YGC-xxx-3B9, 784037YGC-xxx-3B9, 784038YGC-xxx-3B9
- 80-pin plastic QFP (14 × 14 mm, 1.4-mm thick)
 μPD784035YGC-xxx-8BT, 784036YGC-xxx-8BT, 784037YGC-xxx-8BT, 784038YGC-xxx-8BT
- 80-pin plastic TQFP (fine pitch) (12 × 12 mm)
 μPD784035YGK-xxx-BE9^{Note 1}, 784036YGK-xxx-BE9^{Note 1}, 784037YGK-xxx-BE9, 784038YGK-xxx-BE9



Notes 1. Under development

2. TEST pin should be connected to Vsso directly.



P50 to P57

: Port5

A8 to A19 : Address Bus P60 to P67 : Port6 AD0 to AD7 : Address/Data Bus P70 to P77 : Port7

: Pulse Width Modulation Output PWM0, PWM1 ANI0 to ANI7 : Analog Input

ANO0, ANO1 : Analog Output RD : Read Strobe

: Asynchronous Serial Clock REFRQ ASCK, ASCK2 : Refresh Request RESET **ASTB** : Address Strobe : Reset

 AV_{DD} : Analog Power Supply RxD, RxD2 : Receive Data SCK0 to SCK2 AVREF1 to AVREF3: Reference Voltage : Serial Clock **AVss** : Analog Ground SCL : Serial Clock CI : Clock Input SDA : Serial Data **CLKOUT** : Clock Output SI0 to SI2 : Serial Input **HLDAK** : Hold Acknowledge SO0 to SO2 : Serial Output

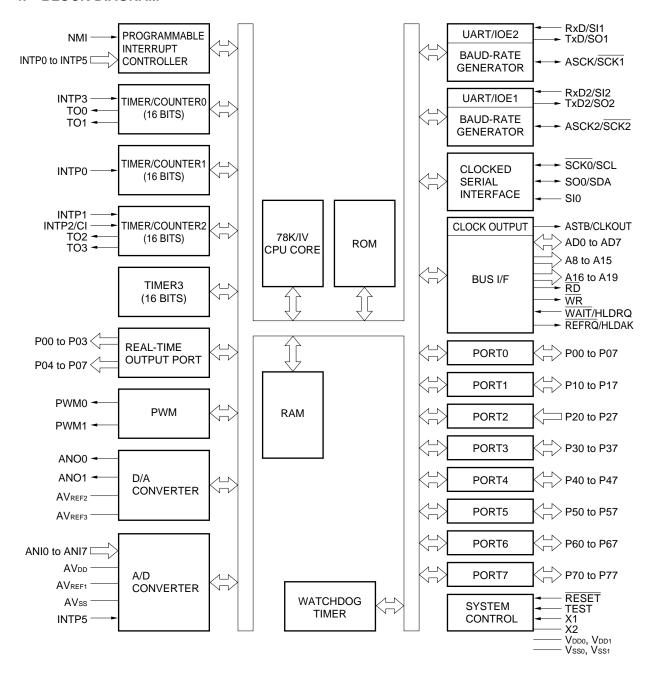
TEST HLDRQ : Hold Request : Test

INTP0 to INTP5 : Interrupt from Peripherals TO0 to TO3 : Timer Output NMI : Non-maskable Interrupt TxD, TxD2 : Transmit Data : Port0 P00 to P07 V_{DD0} to V_{DD1} : Power Supply

P10 to P17 : Port1 Vsso to Vss1 : Ground WAIT : Wait P20 to P27 : Port2

P30 to P37 : Port3 $\overline{\mathsf{WR}}$: Write Strobe P40 to P47 : Port4 X1, X2 : Crystal

4. BLOCK DIAGRAM



Remark The internal ROM and RAM capacities differ depending on the model.



5. PIN FUNCTION

5.1 Port Pins

Pin Name	I/O	Alternate function	Function
P00 to P07	I/O	_	Port 0 (P0): • 8-bit I/O port • Can be used as real-time output port (4 bits × 2). • Can be set in input or output mode bitwise. • Pins set in input mode can be connected to internal pull-up resistors by software. • Can drive transistor.
P10	I/O	PWM0	Port 1 (P1):
P11		PWM1	8-bit I/O port
P12		ASCK2/SCK2	 Can be set in input or output mode bitwise. Pins set in input mode can be connected to internal pull-up
P13		RxD2/SI2	resistors by software.
P14		TxD2/SO2	Can drive LEDs.
P15 to P17		_	
P20	Input	NMI	Port 2 (P2):
P21		INTP0	8-bit input port
P22		INTP1	P20 cannot be used as general-purpose port pin (non-maskable interrupt). However, its input level can be checked by interrupt
P23		INTP2/CI	routine.
P24		INTP3	P22 through P27 can be connected to internal pull-up resistors
P25		INTP4/ASCK/SCK1	by software in 6-bit units. • P25/INTP4/ASCK/SCK1 pin can operate as SCK1 output pin
P26		INTP5	if so specified by CSIM1.
P27		SIO	
P30	I/O	RxD/S1	Port 3 (P3):
P31		TxD/SO1	8-bit I/O port
P32		SCK0/SCL	 Can be set in input or output mode bitwise. Pins set in input mode can be connected to internal pull-up
P33		SO0/SDA	resistors by software.
P34 to P37		TO0 to TO3	
P40 to P47	I/O	AD0 to AD7	Port 4 (P4): • 8-bit I/O port • Can be set in input or output mode bitwise. • Pins set in input mode can be connected to internal pull-up resistors by software. • Can drive LEDs.
P50 to P57	I/O	A8 to A15	Port 5 (P5): • 8-bit I/O port • Can be set in input or output mode bitwise. • Pins set in input mode can be connected to internal pull-up resistors by software. • Can drive LEDs.



Pin Name	I/O	Alternate function	Function
P60 to P63	I/O	A16 to A19	Port6 (P6):
P64		RD	• 8-bit I/O port
P65		WR	Can be set in input or output mode bitwise. Place set in input mode can be connected to internal pull up
P66		WAIT/HLDRQ	 Pins set in input mode can be connected to internal pull-up resistors by software.
P67		REFRQ/HLDAK	, , , , , , , , , , , , , , , , , , , ,
P70 to P77	I/O	AN10 to AN17	Port 7 (P7):
			• 8-bit I/O port
			Can be set in input or output mode bitwise.



5.2 Non-Port Pins

Pin Name	I/O	Alternate function		Function	
TO0 to TO3	Output	P34 to P37	Timer output		
CI	Input	P23/INTP2	Count clock input to timer/counter 2		
RxD	Input	P30/SI1	Serial data input (UART0)		
RxD2	, ,	P13/SI2	Serial data input (UART2)		
TxD	Output	P31/SO1	Serial data output (UART0)		
TxD2	2	P14/SO2	Serial data output (UART2)		
ASCK	Input	P25/INTP4/SCK1	Baud rate clock input (UAR		
ASCK2		P12/SCK2	Baud rate clock input (UAR	,	
SDA	I/O	P33/SO0	Serial data input/output (2-v	,	
SIO	Input	P27	Serial data input (3-wire se	· ,	
SI1		P30/RxD	Serial data input (3-wire se	<u> </u>	
SI2		P13/RxD2	Serial data input (3-wire se	<u> </u>	
SO0	Output	P33/SDA	Serial data output (3-wire s	·	
SO1	- Calpai	P31/TxD	Serial data output (3-wire s	<u>'</u>	
SO2		P14/TxD2	Serial data output (3-wire s	· · · · · · · · · · · · · · · · · · ·	
SCK0	I/O	P32/SCL	Serial clock input/output (3-	,	
SCK1	.,, 0	P25/INTP4/ASCK	Serial clock input/output (3-	,	
SCK2		P12/ASCK2	Serial clock input/output (3-	<u> </u>	
SCL		P32/SCK0	Serial clock input/output (2-	<u> </u>	
NMI	Input	P20	External interrupt requests	_	
INTP0	, input	P21		Count clock input to timer/counter 1 Capture trigger signal of CR11 or CR12	
INTP1		P22		Count clock input to timer/counter 2 Capture trigger signal of CR22	
INTP2		P23/CI		Count clock input to timer/counter 2 Capture trigger signal of CR21	
INTP3		P24		Count clock input to timer/counter 0 Capture trigger signal of CR02	
INTP4		P25/ASCK/SCK1		_	
INTP5		P26		Conversion start trigger input to A/D converter	
AD0 to AD7	I/O	P40 to P47	Time-division address/data	bus (for external memory connection)	
A8 to A15	Output	P50 to P57	Higher address bus (for ext	ternal memory connection)	
A16 to A19	Output	P60 to P63	Higher address when addres	s is extended (for external memory connection)	
RD	Output	P64	Read strobe to external me	mory	
WR	Output	P65	Write strobe to external memory		
WAIT	Input	P66/HLDRQ	Wait insertion		
REFRQ	Output	P67/HLDAK	Refresh pulse output to external pseudo static memory		
HLDRQ	Input	P66/WAIT	Bus hold request input		
HLDAK	Output	P67/REFRQ	Bus hold acknowledge output		
ASTB	Output	CLKOUT		time-division address (A0 through A7)	
			(when accessing external n	,	
CLKOUT	Output	ASTB	Clock output		

*	
*	
*	
4	

Pin Name	I/O	Alternate function	Function	
RESET	Input	_	Chip reset	
X1	Input	_	Crystal connection for system clock oscillation	
X2	_		(Clock can also be input to X1).	
ANI0 to ANI7	Input	P70 to P77	Analog voltage input to A/D converter	
ANO0, ANO1	Output	_	Analog voltage output from D/A converter	
AV _{REF1}	-	_	Reference voltage to A/D converter	
AVREF2, AVREF3			Reference voltage to D/A converter	
AV _{DD}			A/D converter power supply	
AVss			A/D converter GND	
V _{DD0} Note1	7 _{DD0} Note1		Positive power supply of the port block	
V _{DD1} Note1			Positive power supply except for the port block	
V _{SS0} Note2			GND of the port block	
V _{SS1} Note2			GND except for the port block	
TEST			Directly connect to Vsso (IC test pin).	

Notes 1. The potential of the V_{DD0} pin must be equal to that of the V_{DD1} pin.

2. The potential of the Vsso pin must be equal to that of the Vss1 pin.



5.3 Types of Pin I/O Circuits and Connections for Unused Pins

Table 5-1 shows types of pin I/O circuits and the connections for unused pins. For the input/output circuit of each type, refer to Figure 5-1.

★ Table 5-1. Types of Pin I/O Circuits and Connections for Unused Pins

Pin Name	I/O Circuit Type	I/O	Recommended Connection for Unused Pins
P00 to P07	5-H	I/O	Input: Connect to VDD0
P10/PWM0 P11/PWM1			Output: Open
P12/ASCK2/SCK2	8-C		
P13/RxD2/SI2	5-H		
P14/TxD2/SO2			
P15 to P17			
P20/NMI	2	Input	Connect to VDD0 or VSS0.
P21/INTP0			
P22/INTP1	2-C		Connect to VDDO.
P23/INTP2/CI			
P24/INTP3			
P25/INTP4/ASCK/SCK1	8-C	I/O	Input: Connect to VDD0 Output: Open
P26/INTP5	2-C	Input	Connect to V _{DDO} .
P27/SI0			
P30/RxD/SI1	5-H	I/O	Input: Connect to VDD0.
P31/TxD/SO1			Output: Open
P32/SCK0/SCL	10-B		
P33/SO0/SDA			
P34/TO0 to P37/TO3	5-H		
P40/AD0 to P47/AD7			
P50/A8 to P57/A15			
P60/A16 to P63/A19			
P64/RD			
P65/WR			
P66/WAIT/HLDRQ			
P67/REFRQ/HLDAK			
P70/ANI0 to P77/ANI7	20-A	I/O	Input: Connect to VDD0 or Vsso. Output: Open
ANO0, ANO1	12	Output	Open
ASTB/CLKOUT	4-B		

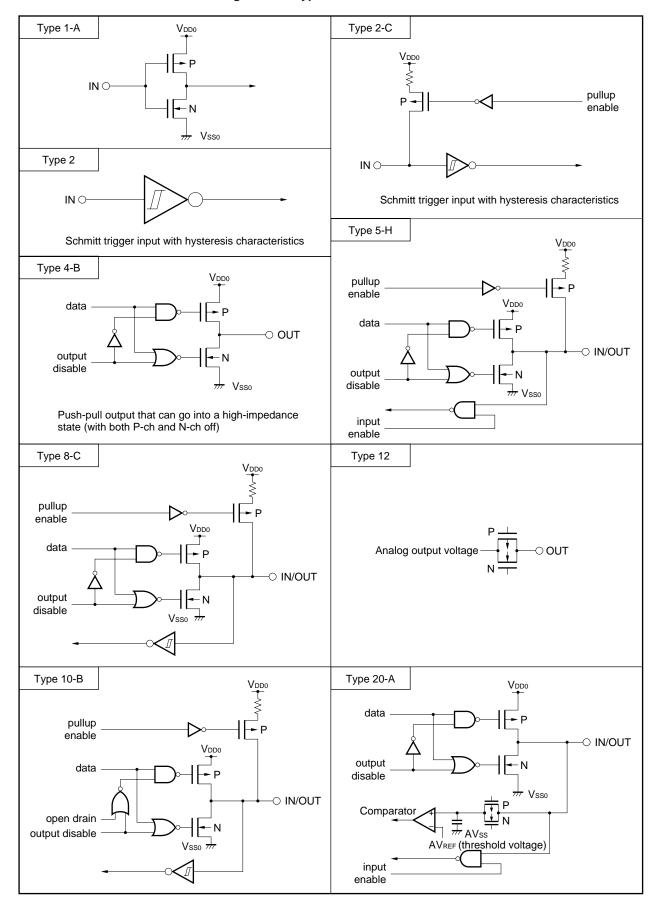


Pin Name	I/O Circuit Type	I/O	Recommended Connection for Unused Pins		
RESET	2	Input	-		
TEST	1-A		Directly connect to Vsso.		
AVREF1 to AVREF3	_		Connect to Vsso.		
AVss					
AV _{DD}			Connect to VDD0.		

Caution Connect an I/O pin whose input/output mode is unstable to V_{DDO} via a resistor of several 10 k Ω (especially if the voltage on the reset input pin rises higher than the low-level input level on power application or when the mode is switched between input and output by software).

Remark Because the circuit type numbers shown in the above table are commonly used with all the models in the 78K Series, these numbers of some models are not serial (because some circuits are not provided to some models).

Figure 5-1. Types of Pin I/O Circuits





6. CPU ARCHITECTURE

6.1 Memory Space

A memory space of 1 MByte can be accessed. Mapping of the internal data area (special function registers and internal RAM) can be specified the LOCATION instruction. The LOCATION instruction must be always executed after RESET cancellation, and must not be used more than once.

(1) When LOCATION 0 instruction is executed

Internal memory

The internal data area and internal ROM area are mapped as follows:

Part Number	Internal Data Area	Internal ROM Area
μPD784035Y	0F700H-0FFFFH	00000H-0BFFFH
μPD784036Y		00000H-0F6FFH
μPD784037Y	0F100H-0FFFFH	00000H-0F0FFH
		10000H-17FFFH
μPD784038Y	0EE00H-0FFFFH	00000H-0FDFFH
		10000H-1FFFFH

Caution The following areas that overlap the internal data area of the internal ROM cannot be used when the LOCATION 0 instruction is executed.

Part Number	Unusable Area
μPD784035Y	_
μPD784036Y	0F700H-0FFFFH (2304 Bytes)
μPD784037Y	0F100H-0FFFFH (3840 Bytes)
μPD784038Y	0EE00H-0FFFFH (4608 Bytes)

• External memory

The external memory is accessed in external memory expansion mode.

(2) When LOCATION 0FH instruction is executed

Internal memory

The internal data area and internal ROM area are mapped as follows:

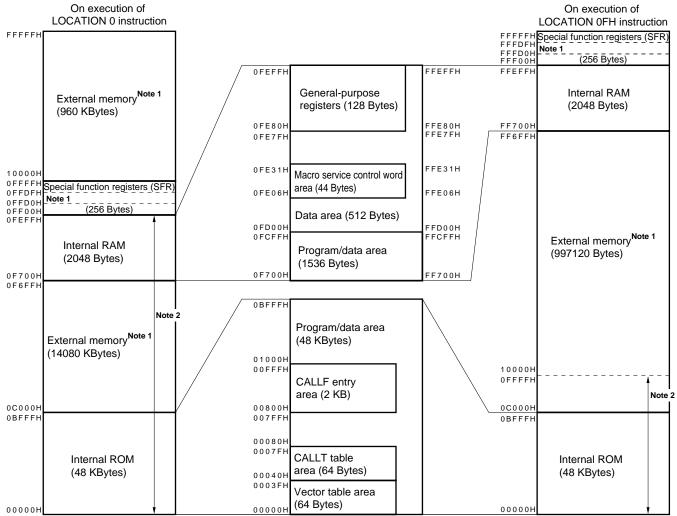
Part Number	Internal Data Area	Internal ROM Area		
μPD784035Y	FF700H-FFFFFH	00000H-0BFFFH		
μPD784036Y		00000H-0FFFFH		
μPD784037Y	FF100H-FFFFFH	00000H-17FFFH		
μPD784038Y	FEE00H-FFFFFH	00000H-1FFFFH		

External memory

The external memory is accessed in external memory expansion mode.

Z

Figure 6-1. Memory Map of μ PD784035Y



Notes 1. Accessed in external memory expansion mode.

2. Base area and entry area for reset or interrupt. However, the internal RAM area is not used as a reset entry area.

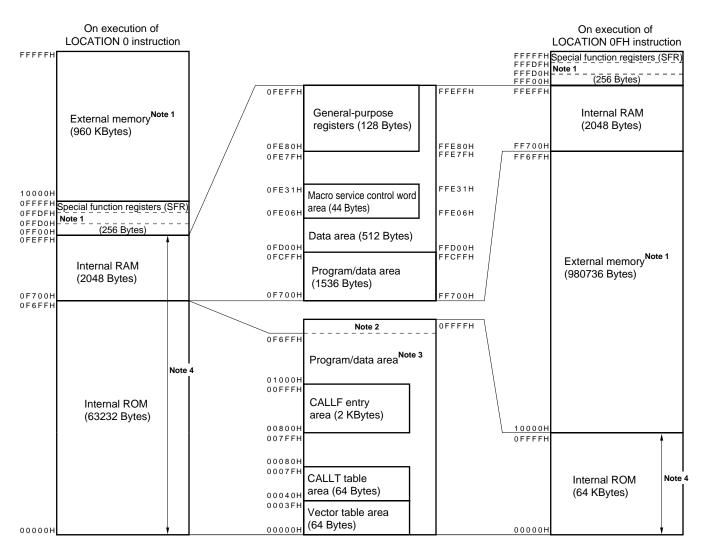


Figure 6-2. Memory Map of μ PD784036Y

- **Notes 1.** Accessed in external memory expansion mode.
 - 2. This 2304-Byte area can be used as an internal ROM only when the LOCATION 0FH instruction is executed.
 - 3. On execution of LOCATION 0 instruction: 63232 Bytes, on execution of LOCATION 0FH instruction: 65536 Bytes
 - 4. Base area and entry area for reset or interrupt. However, the internal RAM area is not used as a reset entry area.

Z

On execution of On execution of LOCATION 0 instruction LOCATION 0FH instruction FFFFFH FFFFH Special function registers (SFR) **FFFDFH** Note 1 FFFD0H (256 Bytes) FFF00H FFEFFH FFEFF OFEFFH External memory Note 1 General-purpose Internal RAM (928 KBytes) registers (128 Bytes) (3584 Bytes) 0FE80H FFE80H FFE7FH FF100H FF0FFH 0FE7FH 18000H 17FFFH Internal ROM FFE31H (32768 Bytes) 0FE31H 10000H Macro service control word 0FFFFH Special function registers (SFR) area (44 Bytes) 0FFDFH 0FE06H FFE06H Note 1 0FFD0H (256 Bytes) 0FF00H Data area (512 Bytes) 0FEFFH 0FD00H FFD00H 0FCFFH FFCFFH External memory Note 1 Internal RAM Program/data area (946432 Bytes) (3584 Bytes) (3072 Bytes) 0F100H 0F100H FF100H OFOFFH 17FFFH 17FFFH Note 2 0F0FFH Program/data area Note 3 Note 4 01000H 00FFFH CALLF entry Internal ROM area (2 KBytes) (61696 Bytes) 00800H 18000H 007FFH 17FFFI 00080H 0007FH CALLT table Internal ROM Note 4 area (64 Bytes) (96 KBytes) 00040H 0003FH Vector table area

Figure 6-3. Memory Map of μ PD784037Y

Notes 1. Accessed in external memory expansion mode.

00000H

2. This 3840-Byte area can be used as an internal ROM only when the LOCATION 0FH instruction is executed.

00000

- 3. On execution of LOCATION 0 instruction: 94464 Bytes, on execution of LOCATION 0FH instruction: 98304 Bytes
- 4. Base area and entry area for reset or interrupt. However, the internal RAM area is not used as a reset entry area.

(64 Bytes)

00000H

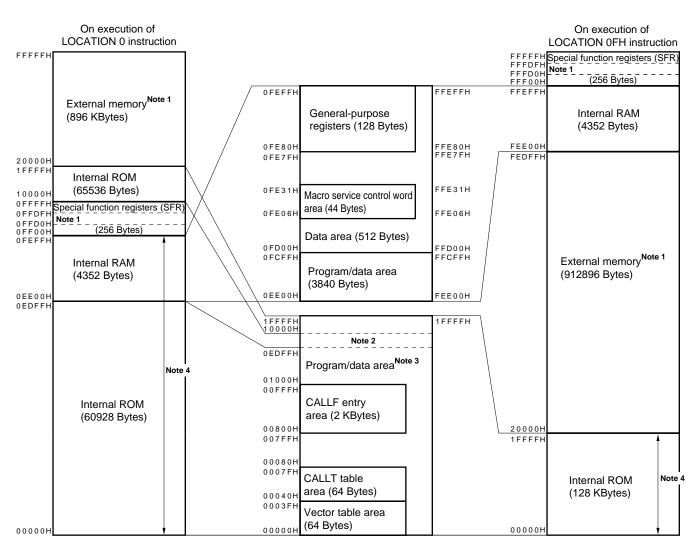


Figure 6-4. Memory Map of μ PD784038Y

Notes 1. Accessed in external memory expansion mode.

- 2. This 4608-Byte area can be used as an internal ROM only when the LOCATION 0FH instruction is executed.
- 3. On execution of LOCATION 0 instruction: 126464 Bytes, on execution of LOCATION 0FH instruction: 131072 Bytes
- 4. Base area and entry area for reset or interrupt. However, the internal RAM area is not used as a reset entry area.



6.2 CPU Registers

6.2.1 General-purpose registers

Sixteen 8-bit general-purpose registers are available. Two 8-bit registers can be also used in pairs as a 16-bit register. Of the 16-bit registers, four can be used in combination with an 8-bit register for address expansion as 24-bit address specification registers.

Eight banks of these registers are available which can be selected by using software or the context switching function.

The general-purpose registers except V, U, T, and W registers for address expansion are mapped to the internal RAM.

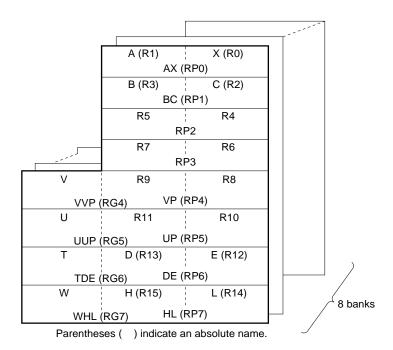


Figure 6-5. General-Purpose Register Format

Caution Registers R4, R5, R6, R7, RP2, and RP3 can be used as X, A, C, B, AX, and BC registers, respectively, by setting the RSS bit of the PSW to 1. However, use this function only for recycling the program of the 78K/III Series.



6.2.2 Control registers

(1) Program counter (PC)

The program counter is a 20-bit register whose contents are automatically updated when the program is executed.

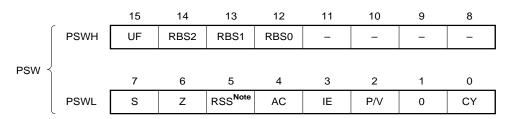
Figure 6-6. Program Counter (PC) Format



(2) Program status word (PSW)

This register holds the statuses of the CPU. Its contents are automatically updated when the program is executed.

Figure 6-7. Program Status Word (PSW) Format



Note This flag is provided to maintain compatibility with the 78K/III Series. Be sure to clear this flag to 0, except when the software for the 78K/III Series is used.

(3) Stack pointer (SP)

This is a 24-bit pointer that holds the first address of the stack. Be sure to write 0 to the higher 4 bits of this pointer.

Figure 6-8. Stack Pointer (SP) Format



6.2.3 Special function registers (SFRs)

The special function registers, such as the mode registers and control registers of the internal peripheral hardware, are registers to which special functions are allocated. These registers are mapped to a 256-Byte space of addresses 0FF00H through 0FFFHNote.

Note On execution of the LOCATION 0 instruction. FFF00H through FFFFH on execution of the LOCATION 0FH instruction.

Caution Do not access an address in this area to which no SFR is allocated. If such an address is accessed by mistake, the μ PD784038Y may be in the deadlock status. This deadlock status can be cleared only by inputting the RESET signal.

Table 6-1 lists the special function registers (SFRs). The meanings of the symbols in this table are as follows:

R/W: Read/write
R: Read-only
W: Write-only

• Bit units for manipulation .. Bit units in which the value of the SFR can be manipulated.

SFRs that can be manipulated in 16-bit units can be described as the operand sfrp of an instruction. To specify the address of this SFR, describe an

even address.

SFRs that can be manipulated in 1-bit units can be described as the operand

of a bit manipulation instruction.

• After reset Indicates the status of the register when the RESET signal has been input.

Table 6-1. Special Function Registers (SFRs)

AddressNote	Special Function	Register (SFR) Name	Syr	mbol	R/W	Bit unit	s for man	ipulation	After reset
						1 bit	8 bits	16 bits	
0FF00H	Port 0		P0		R/W	0	0	_	Undefined
0FF01H	Port 1		P1			0	0	_	
0FF02H	Port 2		P2		R	0	0	_	
0FF03H	Port 3		P3		R/W	0	0	_	
0FF04H	Port 4		P4			0	0	_	
0FF05H	Port 5		P5			0	0	-	
0FF06H	Port 6		P6			0	0	-	00H
0FF07H	Port 7		P7			0	0	_	Undefined
0FF0EH		Port 0 buffer register L	P0L			0	0	_	
0FF0FH	Port 0 buffer register H		P0H			0	0	_	
0FF10H	Compare register (tin	ner/counter 0)	CR00)		_	_	0	
0FF12H	Capture/compare reg	ister (timer/counter 0)	CR0	1		_	_	0	
0FF14H	Compare register L (timer/counter 1)	CR10	CR10W		_	0	0	
0FF15H	Compare register H (timer/counter 1)	_			_	_		
0FF16H	Capture/compare reg	ister L (timer/counter 1)	CR11	CR11W		_	0	0	
0FF17H	Capture/compare reg	ister H (timer/counter 1)	_			_	_		
0FF18H	Compare register L (timer/counter 2)	CR20	CR20W		_	0	0	
0FF19H	Compare register H (timer/counter 2)	-			_	_		
0FF1AH	Capture/compare reg	ister L (timer/counter 2)	CR21	CR21W		_	0	0	
0FF1BH	Capture/compare reg	ister H (timer/counter 2)	-			_	_		
0FF1CH	Compare register L (timer 3)	CR30	CR30W		-	0	0	
0FF1DH	Compare register H (timer 3)	-			-	_		
0FF20H	Port 0 mode register		РМ0			0	0	_	FFH
0FF21H	Port 1 mode register		PM1			0	0	_	
0FF23H	Port 3 mode register		РМ3			0	0	_	
0FF24H	Port 4 mode register		PM4			0	0	-	
0FF25H	Port 5 mode register		PM5			0	0	-	
0FF26H	Port 6 mode register		PM6			0	0	-	
0FF27H	Port 7 mode register		PM7			0	0	_	
0FF2EH	Real-time output port control register		RTP	0		0	0	_	00H
0FF30H	Capture/compare control register 0		CRC	0		_	0	_	10H
0FF31H	Timer output control	register	тос			0	0	_	00H
0FF32H	Capture/compare cor	ntrol register 1	CRC	1		_	0	_	
0FF33H	Capture/compare cor	ntrol register 2	CRC	2		_	0	_	10H

Note When the LOCATION 0 instruction is executed. When the LOCATION 0FH instruction is executed, "F0000H" is added to this value.



Address ^{Note 1}	Special Function Register (SFR) Name	Syr	mbol	R/W	Bit units	s for mani	pulation	After reset
					1 bit	8 bits	16 bits	
0FF36H	Capture register (timer/counter 0)	CR02	2	R	-	_	0	0000H
0FF38H	Capture register L (timer/counter 1)	CR12	CR12W		1	0	0	
0FF39H	Capture register H (timer/counter 1)	_			-	-		
0FF3AH	Capture register L (timer/counter 2)	CR22	CR22W		ı	0	0	
0FF3BH	Capture register H (timer/counter 2)	_			-	-		
0FF41H	Port 1 mode control register	РМС	1	R/W	0	0	-	00H
0FF43H	Port 3 mode control register	PMC:	3		0	0	_	
0FF4EH	Pull-up resistor option register	PUO			0	0	-	
0FF50H	Timer register 0	TMO		R	1	-	0	0000H
0FF51H					1	_		
0FF52H	Timer register 1	TM1	TM1W		_	0	0	
0FF53H		_			-	-		
0FF54H	Timer register 2	TM2	TM2W		-	0	0	
0FF55H		_			_	-		
0FF56H	Timer register 3	ТМЗ	TM3W		-	0	0	
0FF57H		_			-	-		
0FF5CH	Prescaler mode register 0	PRM	0	R/W	_	0	-	11H
0FF5DH	Timer control register 0	TMC	0		0	0	_	00H
0FF5EH	Prescaler mode register 1	PRM	1		ı	0	-	11H
0FF5FH	Timer control register 1	TMC	1		0	0	-	00H
0FF60H	D/A conversion value setting register 0	DACS	S0		ı	0	_	
0FF61H	D/A conversion value setting register 1	DACS	S1		ı	0	-	
0FF62H	D/A converter mode register	DAM			0	0	_	03H
0FF68H	A/D converter mode register	ADM			0	0	_	00H
0FF6AH	A/D conversion result register	ADC	3	R	ı	0	_	Undefined
0FF70H	PWM control register	PWM	IC	R/W	0	0	_	05H
0FF71H	PWM prescaler register	PWP	R		ı	0	_	00H
0FF72H	PWM modulo register 0	PWM	10		1	_	0	Undefined
0FF74H	PWM modulo register 1	PWM	11		1	-	0	
0FF7DH	One-shot pulse output control register	OSPC			0	0	_	00H
0FF80H	I ² C bus control register	IICC			0	0	_	
0FF81H	Prescaler mode register for serial clock	SPRI	М		ı	0	-	04H
0FF82H	Clocked serial interface mode register	CSIM	1		0	0	-	00H
0FF83H	Slave address register	SVA		R/W ^{Note 2}	ONote 3	0	_	01H

Notes 1. When the LOCATION 0 instruction is executed. When the LOCATION 0FH instruction is executed, "F0000H" is added to this value.

- 2. Bit 0 is read-only.
- 3. Only bit 0 can be manipulated in bit units.



Address ^{Note 1}	Special Function Register (SFR) Name	Symbol	R/W	Bit unit	s for mani	pulation	After reset
				1 bit	8 bits	16 bits	
0FF84H	Clocked serial interface mode register 1	CSIM1	R/W	0	0	_	00H
0FF85H	Clocked serial interface mode register 2	CSIM2		0	0	-	
0FF86H	Serial shift register	SIO		ı	0	_	
0FF88H	Asynchronous serial interface mode register	ASIM		0	0	_	
0FF89H	Asynchronous serial interface mode register 2	ASIM2		0	0	-	
0FF8AH	Asynchronous serial interface status register	ASIS	R	0	0	_	
0FF8BH	Asynchronous serial interface status register 2	ASIS2		0	0	_	
0FF8CH	Serial receive buffer: UART0	RXB		-	0	-	Undefined
	Serial transmit shift register: UART0	TXS	W	-	0	-	
	Serial shift register: IOE1	SIO1	R/W	-	0	_	
0FF8DH	Serial receive buffer: UART2	RXB2	R	-	0	-	
	Serial transmit shift register: UART2	TXS2	W	ı	0	_	
	Serial shift register: IOE2	SIO2	R/W	ı	0	_	
0FF90H	Baud rate generator control register	BRGC		-	0	-	00H
0FF91H	Baud rate generator control register 2	BRGC2		-	0	-	
0FFA0H	External interrupt mode register 0	INTM0		0	0	_	
0FFA1H	External interrupt mode register 1	INTM1		0	0	-	
0FFA4H	Sampling clock select register	SCS0		ı	0	_	
0FFA8H	In-service priority register	ISPR	R	0	0	_	
0FFAAH	Interrupt mode control register	IMC	R/W	0	0	-	80H
0FFACH	Interrupt mask register 0L	MK0L MK0		0	0	0	FFFFH
0FFADH	Interrupt mask register 0H	МКОН		0	0		
0FFAEH	Interrupt mask register 1L	MK1L		0	0	_	FFH
0FFC0H	Standby control register	STBC		ı	ONote 2	_	30H
0FFC2H	Watchdog timer mode register	WDM		-	ONote 2	_	00H
0FFC4H	Memory expansion mode register	MM		0	0	-	20H
0FFC5H	Hold mode register	HLDM		0	0	_	00H
0FFC6H	Clock output mode register	CLOM		0	0	_	
0FFC7H	Programmable wait control register 1	PWC1		1	0	-	AAH
0FFC8H	Programmable wait control register 2	PWC2		-	_	0	AAAAH

Notes 1. When the LOCATION 0 instruction is executed. When the LOCATION 0FH instruction is executed, "F0000H" is added to this value.

2. Data can be written by using only a dedicated instruction such as "MOV STBC, #byte instruction" and "MOV WDM, #byte instruction", and cannot be written with any other instructions.



Address ^{Note}	Special Function Register (SFR) Name	Symbol	R/W	Bit units for manipulation			After reset
				1 bit	8 bits	16 bits	
0FFCCH	Refresh mode register	RFM	R/W	0	0	_	00H
0FFCDH	Refresh area specification register	RFA		0	0	_	
0FFCFH	Oscillation stabilization time specification register	OSTS		_	0	_	
0FFD0H- 0FFDFH	External SFR area	_		0	0	_	_
0FFE0H	Interrupt control register (INTP0)	PIC0		0	0	_	43H
0FFE1H	Interrupt control register (INTP1)	PIC1		0	0	_	
0FFE2H	Interrupt control register (INTP2)	PIC2		0	0	_	
0FFE3H	Interrupt control register (INTP3)	PIC3		0	0	_	
0FFE4H	Interrupt control register (INTC00)	CIC00		0	0	_	
0FFE5H	Interrupt control register (INTC01)	CIC01		0	0	_	
0FFE6H	Interrupt control register (INTC10)	CIC10		0	0	_	
0FFE7H	Interrupt control register (INTC11)	CIC11		0	0	_	
0FFE8H	Interrupt control register (INTC20)	CIC20		0	0	_	
0FFE9H	Interrupt control register (INTC21)	CIC21		0	0	_	
0FFEAH	Interrupt control register (INTC30)	CIC30		0	0	_	
0FFEBH	Interrupt control register (INTP4)	PIC4		0	0	_	
0FFECH	Interrupt control register (INTP5)	PIC5		0	0	_	
0FFEDH	Interrupt control register (INTAD)	ADIC		0	0	_	
0FFEEH	Interrupt control register (INTSER)	SERIC		0	0	_	
0FFEFH	Interrupt control register (INTSR)	SRIC		0	0	_	
	Interrupt control register (INTCSI1)	CSIIC1		0	0	_	
0FFF0H	Interrupt control register (INTST)	STIC		0	0	_	
0FFF1H	Interrupt control register (INTCSI)	CSIIC		0	0	_	
0FFF2H	Interrupt control register (INTSER2)	SERIC2		0	0	_	
0FFF3H	Interrupt control register (INTSR2)	SRIC2		0	0	_	
	Interrupt control register (INTCSI2)	CSIIC2		0	0	_	
0FFF4H	Interrupt control register (INTST2)	STIC2		0	0	_	
0FFF5H	Interrupt control register (INTSPC)	SPCIC		0	0	_	

Note When the LOCATION 0 instruction is executed. When the LOCATION 0FH instruction is executed, "F0000H" is added to this value.



7. PERIPHERAL HARDWARE FUNCTIONS

7.1 Ports

The ports shown in Figure 7-1 are provided to make various control operations possible. Table 7-1 shows the function of each port. Ports 0 through 6 can be connected to internal pull-up resistors by software when inputting.

P00 Port 0 P07 P10 Port 1 P17 P20-P27 Port 2 P30 Port 3 P37 P40 Port 4 P47 P50 Port 5 P57 P60 Port 6 P67 P70 Port 7 P77

Figure 7-1. Port Configuration

Table 7-1. Port Functions

Port Name	Pin Name	Function	Specification of Pull-up Resistor Connection by Software
Port 0	P00 to P07	 Can be set in input or output mode in 1-bit units. Can operate as 4-bit real-time output port (P00 through P03 and P04 through P07) Can drive transistor. 	All port pins in input mode
Port 1	P10 to P17	Can be set in input or output mode in 1-bit units. Can drive LEDs.	All port pins in input mode
Port 2	P20 to P27	• Input port	In 6-bit units (P22 through P27)
Port 3	P30 to P37	Can be set in input or output mode in 1-bit units.	All port pins in input mode
Port 4	P40 to P47	Can be set in input or output mode in 1-bit units. Can drive LEDs.	All port pins in input mode
Port 5	P50 to P57	Can be set in input or output mode in 1-bit units. Can drive LEDs.	All port pins in input mode
Port 6	P60 to P67	Can be set in input or output mode in 1-bit units.	All port pins in input mode
Port 7	P70 to P77	Can be set in input or output mode in 1-bit units.	_

7.2 Clock Generation Circuit

An on-chip clock generation circuit necessary for operation is provided. This clock generation circuit has a divider circuit. If high-speed operation is not necessary, the internal operating frequency can be lowered by the divider circuit to reduce the current consumption.

X1 O f_{XX} Oscillation 1/2 1/2 1/2 1/2 circuit X2 ○ Selector CPU Peripheral circuit fxx/2 UART/IOE INTP0 noise reduction circuit Oscillation stabilization timer

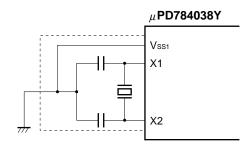
Figure 7-2. Block Diagram of Clock Generation Circuit

 $\textbf{Remark} \quad \text{fxx} \, : \, \text{oscillation frequency or external clock input}$

fclk: internal operating frequency

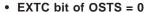
Figure 7-3. Example of Using Oscillation Circuit

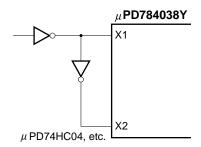
(1) Crystal/ceramic oscillation

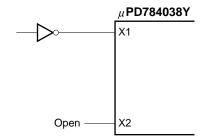


(2) External clock

• EXTC bit of OSTS = 1







Caution When using the clock oscillation circuit, wire the dotted portion in the above figure as follows to avoid adverse influences of wiring capacitance.

- · Keep the wiring length as short as possible.
- · Do not cross the wiring with other signal lines.
- . Do not route the wiring in the vicinity of lines through which a high alternating current flows.
- Always keep the potential at the ground point of the capacitor in the oscillation circuit the same as Vss1. Do not ground to a ground pattern through which a high current flows.
- Do not extract signals from the oscillation circuit.

7.3 Real-Time Output Port

The real-time output port outputs data stored in a buffer in synchronization with the coincidence interrupt generated by timer/counter 1 or with an external interrupt. As a result, pulses without jitter can be output.

The real-time output port is therefore ideal for applications where arbitrary patterns must be output at specific intervals (such as open loop control of a stepping motor).

The real-time output port mainly consists of port 0 and port 0 buffer registers (P0H and P0L) as shown in Figure 7-4.

Internal bus 8 4 4 Buffer register Real-time output port 8 control register (RTPC) P0H P₀L INTP0 (from external source) 4 4 Output trigger INTC10 (from timer/counter 1) control circuit INTC11 (from timer/counter 1) -Output latch (P0) P07 P00

Figure 7-4. Block Diagram of Real-Time Output Port



7.4 Timer/Counter

Three units of timers/counters and one unit of timer are provided.

Because a total of seven interrupt requests are supported, these timers/counters and timer can be used as seven units of timers/counters.

Table 7-2. Operations of Timers/Counters

	Name	Timer/Counter 0	Timer/Counter 1	Timer/Counter 2	Timer 3
Item					
Count width	8 bits	_	0	0	0
	16 bits	0	0	0	0
Operation	Interval timer	2ch	2ch	2ch	1ch
mode	External event counter	0	0	0	-
	One-shot timer	_	_	0	-
Function	Timer output	2ch	_	2ch	_
	Toggle output	0	_	0	-
	PWM/PPG output	0	_	0	_
	One-shot pulse output ^{Note}	0	_	_	-
	Real-time output	_	0	_	-
	Pulse width measurement	1 input	1 input	2 inputs	-
	Number of interrupt requests	2	2	2	1

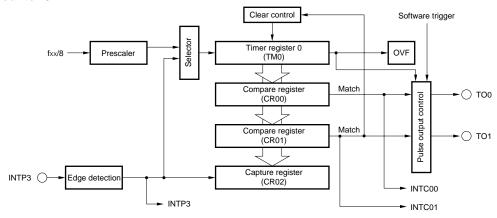
Note The one-shot pulse output function makes a pulse output level active by software and inactive by hardware (interrupt request signal).

This function is different in nature from the one-shot timer function of timer/counter 2.

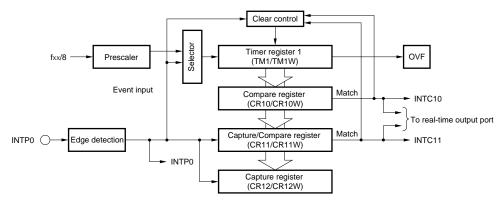


Figure 7-5. Block Diagram of Timers/Counters

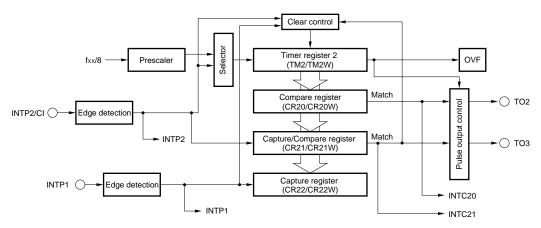
Timer/counter 0



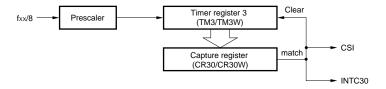
Timer/counter 1



Timer/counter 2



Timer 3



Remark OVF: overflow flag

7.5 PWM Output (PWM0, PWM1)

Two channels of PWM (pulse width modulation) output circuits with a resolution of 12 bits and a repeat frequency of 62.5 kHz (fclk = 16 MHz) are provided. Both these PWM output channels can select a high or low level as the active level. These outputs are ideal for controlling the speed of a DC motor.

Internal bus 16 ∫8 [PWM modulo register PWM control 7 115 8 3 0 PWMn register (PWMC) 4 8 Reload control Output 8-bit down counter Pulse control circuit fclk Prescaler O PWMn (output pin) control 4-bit counter 1/256

Figure 7-6. Block Diagram of PWM Output Unit

Remark n = 0 or 1

7.6 A/D Converter

An analog-to-digital (A/D) converter with eight multiplexed inputs (ANI0 through ANI7) is provided.

This A/D converter is of successive approximation type. The result of conversion is retained by an 8-bit A/D conversion result register (ADCR). Therefore, high-speed, high-accuracy conversion can be performed (conversion time: approx. 7.5 μ s at fcLK = 16 MHz).

A/D conversion can be started in either of the following two modes:

- Hardware start: Conversion is started by trigger input (INTP5).
- Software start: Conversion is started by setting a bit of the A/D converter mode register (ADM).

After started, the A/D converter operates in the following modes:

- Scan mode: Two or more analog inputs are sequentially selected, and data to be converted are obtained from all the input pins.
- Select mode: Only one analog input pin is used to continuously obtain converted values.

These operation modes and whether starting or stopping the A/D converter are specified by the ADM.

When the result of conversion is transferred to the ADCR, interrupt request INTAD is generated. By using this request and macro service, the converted values can be successively transferred to the memory.

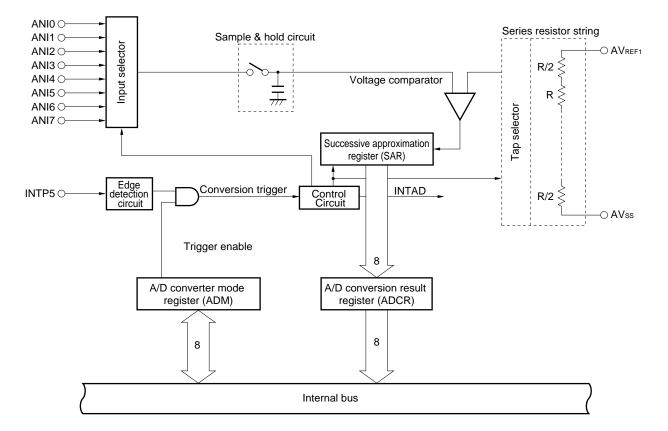


Figure 7-7. Block Diagram of A/D Converter

7.7 D/A Converter

Two circuits of digital-to-analog (D/A) converters are provided. These D/A converters are of voltage output type and have a resolution of 8 bits.

The conversion method is of R-2R resistor ladder type. By writing a value to be output to an 8-bit D/A conversion value setting register (DACSn: n = 0 or 1), an analog value is output to the ANOn (n = 0 or 1) pin. The output voltage range is determined by the voltage applied across the AVREF2 and AVREF3 pins.

Because the output impedance is high, no current can be extracted from the output. If the impedance of the load is low, insert a buffer amplifier between the load and output pin.

The ANOn pin goes into a high-impedance state while the RESET signal is low. When the RESET signal is deasserted, DACSn is cleared to 0.

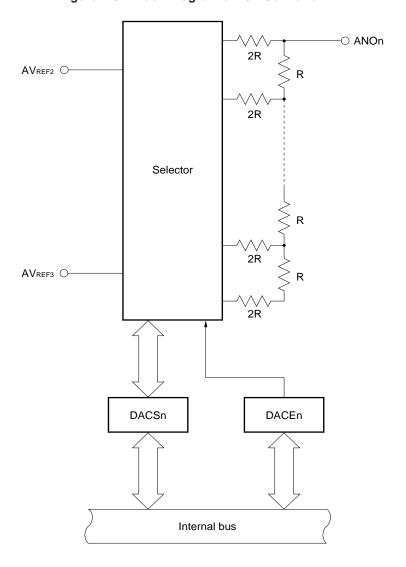


Figure 7-8. Block Diagram of D/A Converter

Remark n = 0 or 1

7.8 Serial Interface

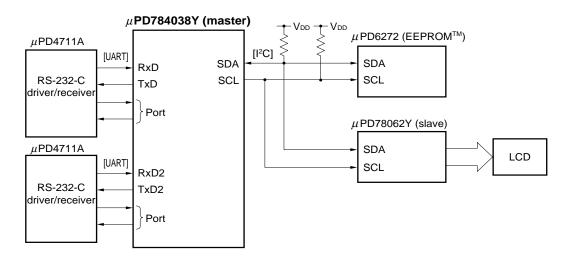
Three independent serial interface channels are provided.

- Asynchronous serial interface (UART)/3-wire serial I/O (IOE) × 2
- Clocked serial interface (CSI) × 1
- 3-wire serial I/O (IOE)
- 2-wire serial I/O (IOE)
- I2C bus interface (I2C)

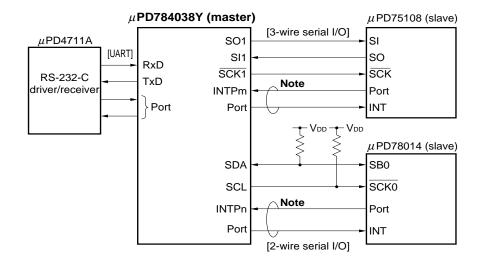
Therefore, communication with an external system and local communication within the system can be simultaneously executed (refer to Figure 7-9).

Figure 7-9. Example of Serial Interface

(a) UART + I2C



(b) UART + 3-wire serial I/O + 2-wire serial I/O



Note Handshake line



7.8.1 Asynchronous serial interface/3-wire serial I/O (UART/IOE)

Two channels of serial interfaces that can select an asynchronous serial interface mode and 3-wire serial I/O mode are provided.

(1) Asynchronous serial interface mode

In this mode, data of 1 byte following the start bit is transferred or received.

Because an on-chip baud rate generator is provided, a wide range of baud rates can be set.

Moreover, the clock input to the ASCK pin can be divided to define a baud rate.

When the baud rate generator is used, a baud rate conforming to the MIDI standard (31.25 kbps) can be also obtained.

Internal bus Receive buffer RXB, RXB2 Receive shift Transmit shift RxD, RxD2 \bigcirc TXS, TXS2 register register TxD, TxD2 \bigcirc INTSR, INTSR2 Trnsmit control Receive control ► INTST, INTST2 INTSER, Parity append parity check INTSER2 Baud rate generator 1/2m $1/2^{n+1}$ ASCK, ASCK2 1/2m

Figure 7-10. Block Diagram in Asynchronous Serial Interface Mode

Remark fxx: oscillation frequency or external clock input

n = 0 through 11

m = 16 through 30

(2) 3-wire serial I/O mode

In this mode, the master device starts transfer by making the serial clock active and transfers 1-byte data in synchronization with this clock.

This mode is used to communicate with a device having the conventional clocked serial interface. Basically, communication is established by using three lines: one serial clock (\overline{SCK}) and two serial data (SI and SO) lines.

★ Generally, a handshake line is necessary to check the communication state.

Internal bus Direction control circuit SIO1, SIO2 Shift register SI1, SI2 (Output latch SO1, SO2 (Interrupt signal INTCSI1, SCK1, SCK2 (Serial clock counter generation circuit INTCSI2 1/m 1/2n+1 fxx/2 Selector Serial clock control circuit

Figure 7-11. Block Diagram in 3-wire Serial I/O Mode

Remark fxx: oscillation frequency or external clock input

n = 0 through 11

m = 1 or 16 through 30

7.8.2 Clocked serial interface (CSI)

In this mode, the master device starts transfer by making the serial clock active and communicates 1-byte data in synchronization with this clock.

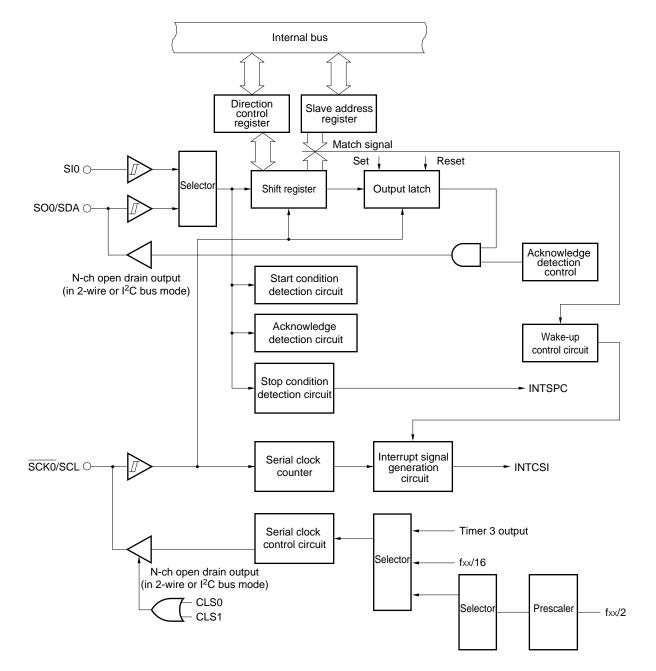


Figure 7-12. Block Diagram of Clocked Serial Interface

Remark fxx: oscillation frequency or external clock input

(1) 3-wire serial I/O mode

This mode is to communicate with devices having the conventional clocked serial interface.

Basically, communication is established in this mode with three lines: one serial clock (SCK0) and two serial data (SI0 and SO0) lines.

Generally, a handshake line is necessary to check the communication status.

(2) 2-wire serial I/O mode

This mode is to transfer 8-bit data by using two lines: serial clock (SCL) and serial data bus (SDA). Generally, a handshake line is necessary to check the communication status.

(3) I2C (Inter IC) bus mode

This mode is to communicate with devices conforming to the I²C bus format.

This mode is to transfer 8-bit data with two or more devices by using two lines: serial clock (SCL) and serial data bus (SDA).

During transfer, a "start condition", "data", and "stop condition" can be output onto the serial data bus. During reception, these data can be automatically detected by hardware.

7.9 Clock Output Function

The operating clock of the CPU can be divided and output to an external device. The pin that outputs the clock can also be used as a 1-bit port.

When this function is used, the local bus interface cannot be used because the ASTB and CLKOUT pins are multiplexed.

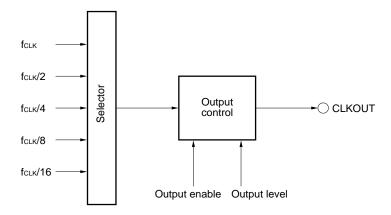


Figure 7-13. Block Diagram of Clock Output Function



7.10 Edge Detection Function

The interrupt input pins (NMI and INTP0 through INTP5) are used not only to input interrupt requests but also to input trigger signals to the internal hardware units. Because these pins operate at an edge of the input signal, they have a function to detect an edge. Moreover, a noise reduction circuit is also provided to prevent erroneous detection due to noise.

Pin Name	Detectable Edge	Noise Reduction
NMI	Either of rising or falling edge	By analog delay
INTP0-INTP3	Either or both of rising and falling edges	By clock sampling ^{Note}
INTP4, INTP5		By analog delay

Note INTP0 can select a sampling clock.

7.11 Watchdog Timer

A watchdog timer is provided to detect a hang up of the CPU. This watchdog timer generates a non-maskable interrupt unless it is cleared by software within a specified interval time. Once enabled to operate, the watchdog timer cannot be stopped by software. Whether the interrupt by the watchdog timer or the interrupt input from the NMI pin takes precedence can be specified.

fclk Timer $fclk/2^{21}$ $fclk/2^{20}$ $fclk/2^{19}$ $fclk/2^{17}$ Clear signal

Figure 7-14. Block Diagram of Watchdog Timer



8. INTERRUPT FUNCTION

As the servicing in response to an interrupt request, the three types shown in Table 8-1 can be selected by program.

Table 8-1. Servicing of Interrupt Request

Servicing Mode	Entity of Servicing	Servicing	Contents of PC and PSW
Vectored interrupt	Software	Branches and executes servicing routine (servicing is arbitrary).	Saves to and restores from stack.
Context switching		Automatically switches register bank, branches and executes servicing routine (servicing is arbitrary).	Saves to or restores from fixed area in register bank
Macro service	Firmware	Executes data transfer between memory and I/O (servicing is fixed)	Retained

8.1 Interrupt Sources

★ Table 8-2 shows the interrupt sources available. As shown, interrupts are generated by 24 types of sources, execution of the BRK instruction or BRKCS instruction, or an operand error.

The priority of interrupt servicing can be set to four levels, so that nesting can be controlled during interrupt servicing and that which of the two or more interrupts that simultaneously occur should be serviced first. When the macro service function is used, however, nesting always proceeds.

The default priority is the priority (fixed) of the service that is performed if two or more interrupt requests, having the same request, simultaneously generate (refer to Table 8-2).



Table 8-2. Interrupt Sources

Туре	Default		Source	Internal/	Macro service
	Priority	Name	Trigger	External	
Software	-	BRK instruction BRKCS instruction	Instruction execution	-	_
		Operand error	If result of exclusive OR between byte of operand and byte is not FFH when "MOV STBC, #byte", "MOV WDM, #byte", or "LOCATION" instruction is executed		
Non-maskable	_	NMI WDT	Detection of pin input edge Overflow of watchdog timer	External Internal	_
	0 (1 : 1 - 1)	1	•		
Maskable	0 (highest)	INTP0	Detection of pin input edge (TM1/TM1W capture trigger, TM1/TM1W event counter input)	External	0
	1	INTP1	Detection of pin input edge (TM2/TM2W capture trigger, TM2/TM2W event counter input)		
	2	INTP2	Detection of pin input edge (TM2/TM2W capture trigger , TM2/TM2W event counter input)		
	3	INTP3	Detection of pin input edge (TM0 capture trigger, TM0 event counter input)		
	4	INTC00	Generation of TM0-CR00 match signal	Internal	0
	5	INTC01	Generation of TM0-CR01 match signal		
	6	INTC10	Generation of TM1-CR10 match signal (in 8-bit operation mode) Generation of TM1W-CR10W match signal (in 16-bit operation mode)		
	7	INTC11	Generation of TM1-CR11 match signal (in 8-bit operation mode) Generation of TM1W-CR11W match signal (in 16-bit operation mode)		
	8	INTC20	Generation of TM2-CR20 match signal (in 8-bit operation mode) Generation of TM2W-CR20W match signal (in 16-bit operation mode)		
	9	INTC21	Generation of TM2-CR21 match signal (in 8-bit operation mode) Generation of TM2W-CR21W match signal (in 16-bit operation mode)		
	10	INTC30	Generation of TM3-CR30 match signal (in 8-bit operation mode) Generation of TM3W-CR30W match signal (in 16-bit operation mode)		
	11	INTP4	Detection of pin input edge	External	0
	12	INTP5	Detection of pin input edge		
	13	INTAD	End of A/D conversion (transfer of ADCR)	Internal	0
	14	INTSER	Occurrence of ASI0 reception error		_
	15	INTSR	End of ASI0 reception or CSI1 transfer		0
		INTCSI1			
	16	INTST	End of ASI0 transfer		
	17	INTCSI	End of CSI1 transfer		
	18 INTSER2 Occurrence of ASI2 reception error 19 INTSR2 End of ASI2 reception or CSI2 transfer				
		0			
	00	INTCSI2	F 1 (A 0 10)		
	20	INTST2	End of ASI2 transfer		

Remark ASI: asynchronous serial interface

CSI: clocked serial interface

8.2 Vectored Interrupt

Execution branches to a servicing routing by using the memory contents of a vector table address corresponding to the interrupt source as the address of the branch destination.

So that the CPU performs interrupt servicing, the following operations are performed:

- On branching: Saves the status of the CPU (contents of PC and PSW) to stack
- On returning: Restores the status of the CPU (contents of PC and PSW) from stack

To return to the main routine from an interrupt service routine, the RETI instruction is used. The branch destination address is in a range of 0 to FFFFH.

Table 8-3. Vector Table Address

Interrupt Source	Vector Table Address
BRK instruction	003EH
Operand error	003CH
NMI	0002H
WDT	0004H
INTP0	0006H
INTP1	0008H
INTP2	000AH
INTP3	000CH
INTC00	000EH
INTC01	0010H
INTC10	0012H
INTC11	0014H
INTC20	0016H
INTC21	0018H
INTC30	001AH
INTP4	001CH
INTP5	001EH
INTAD	0020H
INTSER	0022H
INTSR	0024H
INTCSI1	
INTST	0026H
INTCSI	0028H
INTSER2	002AH
INTSR2	002CH
INTCSI2	
INTST2	002EH
INTSPC	0030H

8.3 Context Switching

When an interrupt request is generated or when the BRKCS instruction is executed, a predetermined register bank is selected by hardware. Context switching is a function that branches execution to a vector address stored in advance in the register bank, and to stack the current contents of the program counter (PC) and program status word (PSW) to the register bank.

The branch address is in a range of 0 to FFFFH.

Register bank n 0000B (0 to 7)<7> Transfer Register bank n (n = 0 to 7) PC19-16 PC15-0 В С <6> Exchange R5 R4 <2> Save (bits 8 through 11 R7 R6 of temporary register) <5> Save ۷P ٧ U <3> Switching of register bank Temporary register (RBS0 to RBS2 \leftarrow n) Т D Ε <4> / RSS ← n \ W L <1> Save /IE **PSW**

Figure 8-1. Context Switching Operation When Interrupt Request Is Generated

8.4 Macro Service

This function is to transfer data between memory and a special function register (SFR) without intervention by the CPU. A macro service controller accesses the memory and SFR in the same transfer cycle and directly transfers data without loading it.

Because this function does not save or restore the status of the CPU, or load data, data can be transferred at high speeds.

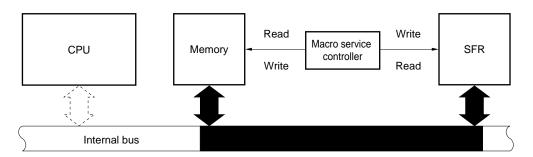
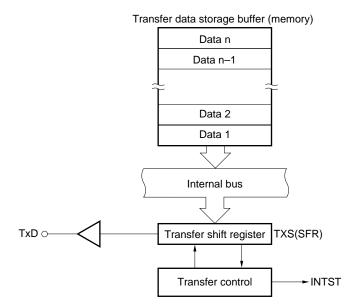


Figure 8-2. Macro Service



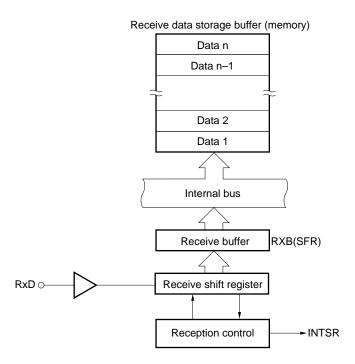
8.5 Application Example of Macro Service

(1) Transfer of serial interface



Each time macro service request (INTST) is generated, the next transfer data is transferred from memory to TXS. When data n (last byte) has been transferred to TXS (when the transfer data storage buffer has become empty), vectored interrupt request (INTST) is generated.

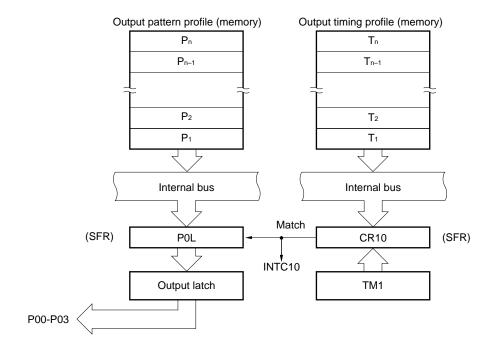
(2) Reception of serial interface



Each time macro service request (INTSR) is generated, the receive data is transferred from RXB to memory. When data n (last byte) has been transferred to memory (when the receive data storage buffer has become full), vectored interrupt request (INTSR) is generated.

(3) Real-time output port

INTC10 and INTC11 serve as the output triggers of the real-time output port. The macro services for these can set the following output pattern and intervals simultaneously. Therefore, INTC10 and INTC11 can control two stepping motors independently of each other. They can also be used for PWM output or to control DC motors.



Each time macro service request (INTC10) is generated, the pattern and timing are transferred to the buffer register (P0L) and compare register (CR10), respectively. When the contents of the timer register 1 (TM1) coincide with those of CR10, INTC10 is generated again, and the contents of P0L are transferred to the output latch. When Tn (last byte) has transferred to CR10, vectored interrupt request (INTC10) is generated.

The same applies to INTC11.

9. LOCAL BUS INTERFACE

The local bus interface can connect an external memory or I/O (memory mapped I/O) and support a memory space of 1 MByte (refer to Figure 9-1).

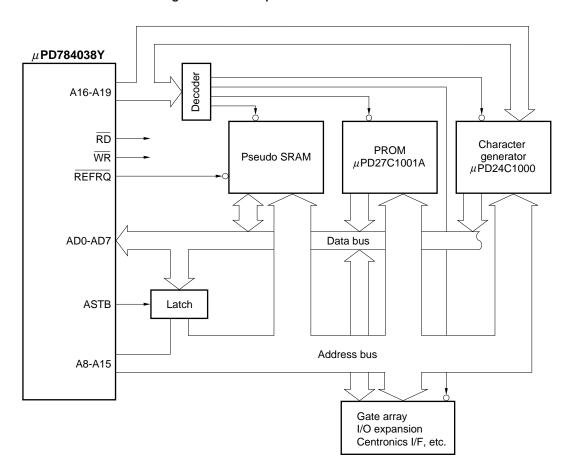


Figure 9-1. Example of Local Bus Interface

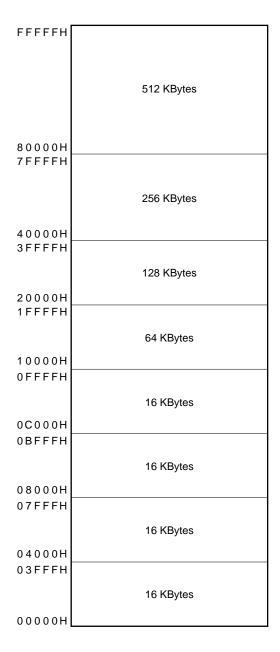
9.1 Memory Expansion

The memory capacity can be expanded in seven steps, from 256 Bytes to 1 MByte, by connecting an external program memory and data memory.

9.2 Memory Space

The 1-MByte memory space is divided into eight spaces of logical addresses. Each space can be controlled by using the programmable wait function and pseudo static RAM refresh function.

Figure 9-2. Memory Space



9.3 Programmable Wait

The memory space can be divided into eight spaces and wait states can be independently inserted in each of these spaces while the \overline{RD} and \overline{WR} signals are active. Even when a memory with a different access time is connected, therefore, the efficiency of the entire system does not drop.

In addition, an address wait function that extends the active period of the ASTB signal is also provided so as to have a sufficient address decode time (this function can be set to the entire space).

9.4 Pseudo Static RAM Refresh Function

The following refresh operations can be performed:

- Pulse refresh: A bus cycle that outputs a refresh pulse to the REFRQ pin at a fixed cycle is inserted. The memory spaces is divided into eight spaces, and a refresh pulse can be output from the REFRQ pin while a specified memory space is accessed. Therefore, the normal memory access is not kept to wait by the refresh cycle.
- Power-down self-refresh: The low level is output to the REFRQ pin in the standby mode to retain the contents
 of the pseudo static RAM.

9.5 Bus Hold Function

A bus hold function is provided to facilitate connection of a DMA controller. When a bus hold request signal (HLDRQ) is received from an external bus master, the address bus, address/data bus, and ASTB, $\overline{\text{RD}}$, and $\overline{\text{WR}}$ pins go into a high-impedance state when the current bus cycle has been completed. This makes the bus hold acknowledge (HLDAK) signal active, and releases the bus to the external bus master.

Note that, while the bus hold function is used, the external wait function and pseudo static RAM refresh function cannot be used.

10. STANDBY FUNCTION

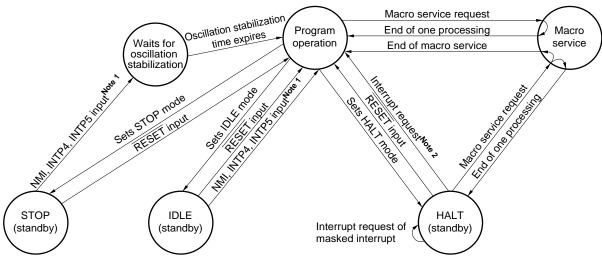
This function is to reduce the power dissipation of the chip, and can be used in the following modes:

- HALT mode: Stops supply of the operating clock to the CPU. This mode is used in combination with the normal operation mode for intermittent operation to reduce the average power dissipation.
- IDLE mode: Stops the entire system with the oscillation circuit continuing operation. The power dissipation in this mode is close to that in the STOP mode. However, the time required to restore the normal program operation from this mode is almost the same as that from the HALT mode.
- STOP mode: Stops the oscillator and thereby to stop all the internal operations of the chip. Consequently, the power dissipation is minimized with only leakage current flowing.

These modes are programmable.

The macro service can be started from the HALT mode.

Figure 10-1. Transition of Standby Status



- Notes 1. When INTP4 and INTP5 are not masked
 - 2. Only interrupt requests that are not masked

Remark Only the externally input NMI is valid. The watchdog timer cannot be used to release the standby mode (STOP/IDLE mode).



11. RESET FUNCTION

When the low level is input to the RESET pin, the internal hardware is initialized (reset status). When the RESET pin goes high, the following data are set to the program counter (PC).

- · Lower 8 bits of PC: contents of address 0000H
- · Middle 8 bits of PC: contents of address 0001H
- Higher 4 bits of PC: 0

Program execution is started from a branch destination address which is the contents of the PC. Therefore, the system can be reset and started from any address.

Set the contents of each register by program as necessary.

The RESET input circuit has a noise reduction circuit to prevent malfunctioning due to noise. This noise reduction circuit is a sampling circuit by analog delay.

Delay Initialize PC Executes instruction at reset start address

RESET (input)

Reset starts Reset ends

Figure 11-1. Accepting RESET Signal

Assert the RESET signal active until the oscillation stabilization time (approx. 40 ms) elapses to execute a power-ON reset operation.

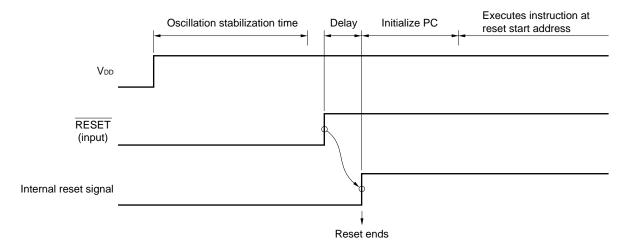


Figure 11-2. Power-ON Reset Operation



12. INSTRUCTION SET

(1) 8-bit instructions (The instructions in parentheses are combinations realized by describing A as r) MOV, XCH, ADD, ADDC, SUB, SUBC, AND, OR, XOR, CMP, MULU, DIVUW, INC, DEC, ROR, ROL, RORC, ROLC, SHR, SHL, ROR4, DBNZ, PUSH, POP, MOVM, XCHM, CMPME, CMPMNE, CMPMNC, CMPMC, MOVBK, XCHBK, CMPBKE, CMPBKNE, CMPBKNC, CMPBKC, CHIKL, CHKLA

Table 12-1. Instruction List by 8-Bit Addressing

Second Operand First Operand	#byte	А	r r'	saddr saddr'	sfr	!addr16 !!addr24	mem [saddrp] [%saddrg]	r3 PSWL PSWH	[WHL+]	n	None ^{Note 2}
А	(MOV) ADD ^{Note 1}	(MOV) (XCH) (ADD) ^{Note 1}	MOV XCH (ADD) ^{Note 1}	(MOV)Note 6 (XCH)Note 6 (ADD)Note 1,6	MOV (XCH) (ADD) ^{Note 1}	(MOV) (XCH) ADD ^{Note 1}	MOV XCH ADD ^{Note 1}	MOV	(MOV) (XCH) (ADD) ^{Note 1}		
г	MOV ADD ^{Note 1}	(MOV) (XCH) (ADD) ^{Note 1}	MOV XCH ADD ^{Note 1}	MOV XCH ADD ^{Note 1}	MOV XCH ADD ^{Note 1}	MOV XCH				RORNote 3	MULU DIVUW INC DEC
saddr	MOV ADD ^{Note 1}	(MOV) ^{Note 6} (ADD) ^{Note 1}	MOV ADD ^{Note 1}	MOV XCH ADD ^{Note 1}							INC DEC DBNZ
sfr	MOV ADD ^{Note 1}	MOV (ADD) ^{Note 1}	MOV ADD ^{Note 1}								PUSH POP CHKL
!addr16 !!addr24	MOV	(MOV) ADD ^{Note 1}	MOV								
mem [saddrp] [%saddrg]		MOV ADD ^{Note 1}									
mem3											ROR4 ROL4
r3 PSWL PSWH	MOV	MOV									
B, C											DBNZ
STBC, WDM	MOV										
[TDE+] [TDE-]		(MOV) (ADD) ^{Note 1} MOVM ^{Note 4}							MOVBKNote 5		

Notes 1. The operands of ADDC, SUB, SUBC, AND, OR, XOR, and CMP are the same as that of ADD.

- 2. Either the second operand is not used, or the second operand is not an operand address.
- 3. The operands of ROL, RORC, ROLC, SHR, and SHL are the same as that of ROR.
- 4. The operands of XCHM, CMPME, CMPMNE, CMPMNC, and CMPMC are the same as that of MOVM.
- **5.** The operands of XCHBK, CMPBKE, CMPBKNE, CMPBKNC, and CMPBKC are the same as that of MOVBK.
- 6. The code length of some instructions having saddr2 as saddr in this combination is short.

(2) 16-bit instructions (The instructions in parentheses are combinations realized by describing AX as rp)

MOVW, XCHW, ADDW, SUBW, CMPW, MULUW, MULW, DIVUX, INCW, DECW, SHRW, SHLW, PUSH, POP, ADDWG, SUBWG, PUSHU, POPU, MOVTBLW, MACW, MACSW, SACW

Table 12-2. Instruction List by 16-Bit Addressing

Second Operand	#word	AX	rp	saddrp	sfrp	!addr16	mem	[WHL+]	byte	n	None ^{Note 2}
			rp'	saddrp'		!!addr24	[saddrp]				
First Operand							[%saddrg]				
AX	(MOVW)	(MOVW)	(MOVW)	(MOVW)Note 3	MOVW	(MOVW)	MOVW	(MOVW)			
	ADDWNote 1	(XCHW)	(XCHW)	(XCHW)Note 3	(XCHW)	XCHW	XCHW	(XCHW)			
		(ADD)Note 1	(ADDW)Note 1	(ADDW) ^{Note 1,3}	(ADDW)Note 1						
rp	MOVW	(MOVW)	MOVW	MOVW	MOVW	MOVW				SHRW	MULWNote 4
	ADDWNote 1	(XCHW)	XCHW	XCHW	XCHW					SHLW	INCW
		(ADDW)Note 1	ADDWNote 1	ADDWNote 1	ADDWNote 1						DECW
saddrp	MOVW	(MOVW)Note 3	MOVW	MOVW							INCW
	ADDW ^{Note 1}	(ADDW)Note 1	ADDWNote 1	XCHW							DECW
				ADDWNote 1							
sfrp	MOVW	MOVW	MOVW								PUSH
	ADDWNote 1	(ADDW)Note 1	ADDWNote 1								POP
!addr16	MOVW	(MOVW)	MOVW						MOVTBLW		
!!addr24											
mem		MOVW									
[saddrp]											
[%saddrg]											
PSW											PUSH
											POP
SP	ADDWG										
	SUBWG										
post											PUSH
											POP
											PUSHU
											POPU
[TDE+]		(MOVW)						SACW			
byte											MACW
											MACSW

Notes 1. The operands of SUBW and CMPW are the same as that of ADDW.

- 2. Either the second operand is not used, or the second operand is not an operand address.
- 3. The code length of some instructions having saddrp2 as saddrp in this combination is short.
- 4. The operands of MULUW and DIVUX are the same as that of MULW.



(3) 24-bit instructions (The instructions in parentheses are combinations realized by describing WHL as rg)

MOVG, ADDG, SUBG, INCG, DECG, PUSH, POP

Table 12-3. Instruction List by 24-Bit Addressing

Second Operand	#imm24	WHL	rg	saddrg	!!addr24	mem1	[%saddrg]	SP	None ^{Note}
			rg'						
First Operand									
WHL	(MOVG)	(MOVG)	(MOVG)	(MOVG)	(MOVG)	MOVG	MOVG	MOVG	
	(ADDG)	(ADDG)	(ADDG)	ADDG					
	(SUBG)	(SUBG)	(SUBG)	SUBG					
rg	MOVG	(MOVG)	MOVG	MOVG	MOVG				INCG
	ADDG	(ADDG)	ADDG						DECG
	SUBG	(SUBG)	SUBG						PUSH
									POP
saddrg		(MOVG)	MOVG						
!!addr24		(MOVG)	MOVG						
mem1		MOVG							
[%saddrg]		MOVG				·		·	
SP	MOVG	MOVG							INCG
									DECG

Note Either the second operand is not used, or the second operand is not an operand address.

(4) Bit manipulation instructions

MOV1, AND1, OR1, XOR1, SET1, CLR1, NOT1, BT, BF, BTCLR, BFSET

Table 12-4. Bit Manipulation Instructions

Second Operand	CY	saddr.bit sfr.bit	/saddr.bit /sfr. bit	None ^{Note}
		A.bit X.bit	/A.bit /X.bit	
		PSWL.bit PSWH.bit	/PSWL.bit /PSWH.bit	
		mem2.bit	/mem2.bit	
First Operand		!addr16.bit !!addr24.bit	/!addr16.bit /!!addr24.bit	
CY		MOV1	AND1	NOT1
		AND1	OR1	SET1
		OR1		CLR1
		XOR1		
saddr.bit	MOV1			NOT1
sfr.bit				SET1
A.bit				CLR1
X.bit				BF
PSWL.bit				вт
PSWH.bit				BTCLR
mem2.bit				BFSET
!addr16.bit				
!!addr24.bit				

Note Either the second operand is not used, or the second operand is not an operand address.



(5) Call and return/branch instructions

CALL, CALLF, CALLT, BRK, RET, RETI, RETB, RETCS, RETCSB, BRKCS, BR, BNZ, BNE, BZ, BE, BNC, BNL, BC, BL, BNV, BPO, BV, BPE, BP, BN, BLT, BGE, BLE, BGT, BNH, BH, BF, BT, BTCLR, BFSET, DBNZ

Table 12-5. Call and Return/Branch Instructions

Operand of Instruction	\$addr20	\$!addr20	!addr16	!!addr20	rp	rg	[rp]	[rg]	!addr11	[addr5]	RBn	None
Address												
Basic instruction	BCNote	CALL	CALL	CALL	CALL	CALL	CALL	CALL	CALLF	CALLF	BRKCS	BRK
	BR	BR	BR	BR	BR	BR	BR	BR				RET
			RETCS									RETI
			RETCSB									RETB
Compound instruction	BF											
	ВТ											
	BTCLR											
	BFSET											
	DBNZ											

Note The operands of BNZ, BNE, BZ, BE, BNC, BNL, BL, BNV, BPO, BV, BPE, BP, BN, BLT, BGE, BLE, BGT, BNH, and BH are the same as BC.

(6) Other instructions

ADJBA, ADJBS, CVTBW, LOCATION, SEL, NOT, EI, DI, SWRS



★ 13. ELECTRICAL SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	Vdd		-0.5 to +7.0	V
	AVDD		AVss to Vpp+0.5	V
	AVss		-0.5 to +0.5	V
Input voltage	Vı		-0.5 to VDD+0.5	V
Output voltage	Vo		-0.5 to VDD+0.5	V
Low-level output	lol	Per pin	15	mA
current		Total of all output pins	100	mA
High-level output	Іон	Per pin	-10	mA
current		Total of all output pins	-100	mA
A/D converter reference input voltage	AVREF1		-0.5 to VDD+0.3	V
D/A converter reference	AVREF2		-0.5 to VDD+0.3	V
input voltage	AV _{REF3}		-0.5 to VDD+0.3	V
Operating ambient temperature	Та		-40 to +85	°C
Storage temperature	Tstg		-65 to +150	°C

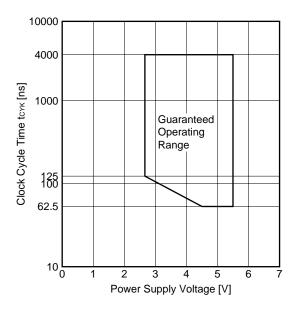
Caution Absolute maximum ratings are rated values beyond which physical damage will be caused to the product; if the rated value of any of the parameters in the above table is exceeded, even momentarily, the quality of the product may deteriorate. Always use the product within its rated values.



OPERATING CONDITIONS

• Operating ambient temperature (Ta) : -40 to $+85^{\circ}$ C • Rising time and falling time (tr, tf) (at pins which are not specified): 0 to 200 μ s • Power supply voltage and clock cycle time : See Figure 13-1

Figure 13-1. Power Supply Voltage and Clock Cycle Time



CAPACITANCE (TA = 25° C, VDD = Vss = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input capacitance	Сі	f = 1 MHz		10	pF	
Output capacitance	Co	Unmeasured pins returned to 0 V.			10	pF
I/O capacitance	Сю				10	pF



OSCILLATOR CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = +4.5 \text{ to } 5.5 \text{ V}$, $V_{SS} = 0 \text{ V}$)

Resonator	Recommended Circuit	Parameter	MIN.	MAX.	Unit
Ceramic resonator or crystal resonator	Vss1 X1 X2 C1 — C2	Oscillator frequency (fxx)	4	32	MHz
External clock		X1 input frequency (fx)	4	32	MHz
	X1 X2	X1 input rising/falling time (txr, txr)	0	10	ns
	HCMOS inverter	X1 input high-/low-level width (twxн, twxL)	10	125	ns

Caution When using the system clock oscillator, wiring the area enclosed with the broken line should be carried out as follows to avoid an adverse effect from wiring capacitance.

- Wiring should be as short as possible.
- Wiring should not cross other signal lines.
- Wiring should not be placed close to a varying high current.
- The potential of the oscillator capacitor ground should be the same as Vss1. Do not ground wiring to a ground pattern in which a high current flows.
- Do not fetch a signal from the oscillator.



OSCILLATOR CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = +2.7 \text{ to } 5.5 \text{ V}$, $V_{SS} = 0 \text{ V}$)

Resonator	Recommended Circuit	Parameter	MIN.	MAX.	Unit
Ceramic resonator or crystal resonator	Vss1 X1 X2 C1 = C2	Oscillator frequency (fxx)	4	16	MHz
External clock		X1 input frequency (fx)	4	16	MHz
	X1 X2 HCMOS inverter	X1 input rising/falling time (txr, txr)	0	10	ns
		X1 input high-/low-level width (twxн, twxL)	10	125	ns

Caution When using the system clock oscillator, wiring the area enclosed with the broken line should be carried out as follows to avoid an adverse effect from wiring capacitance.

- Wiring should be as short as possible.
- Wiring should not cross other signal lines.
- Wiring should not be placed close to a varying high current.
- The potential of the oscillator capacitor ground should be the same as Vss1. Do not ground wiring to a ground pattern in which a high current flows.
- Do not fetch a signal from the oscillator.



DC CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = AV_{DD} = +2.7 \text{ to } 5.5 \text{ V}$, $V_{SS} = AV_{SS} = 0 \text{ V}$) (1/2)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Low-level input voltage	VIL1	For pins other than those described in Notes 1, 2, 3, 4, and 6	-0.3		0.3VDD	V
	VIL2	For pins described in Notes 1, 2, 3, 4, and 6	-0.3		0.2VDD	V
	VIL3	$V_{DD} = +5.0 \text{ V} \pm 10\%$ For pins described in Notes 2 , 3 , and 4	-0.3		+0.8	V
High-level input voltage	VIH1	For pins other than those described in Notes 1 and 6	0.7Vdd		V _{DD} +0.3	V
	V _{IH2}	For pins described in Notes 1 and 6	0.8Vpp		V _{DD} +0.3	V
	V _{IH3}	$V_{DD} = +5.0 \text{ V} \pm 10\%$ For pins described in Notes 2 , 3 , and 4	2.2		Vpp+0.3	V
Low-level output voltage	Vol1	IoL = 2 mA For pins other than those described in Note 6			0.4	V
	V _{OL2}	IoL = 3 mA For pins described in Note 6			0.4	V
		IoL = 6 mA For pins described in Note 6			0.6	V
	V _{OL3}	V _{DD} = +5.0 V±10% I _{OL} = 8 mA For pins described in Notes 2 and 5			1.0	V
High-level output voltage	Voн1	Iон = −2 mA	Vpp-1.0			V
	V _{OH2}	V_{DD} = +5.0 V±10% I_{OH} = -5 mA For pins other than those described in Note 4	VDD-1.4			V
X1 low-level input current	lıL	$EXTC = 0$ $0 \ V \le V_1 \le V_{1L2}$			-30	μΑ
X1 high-level input current	Іін	$EXTC = 0$ $V_{IH2} \le V_I \le V_{DD}$			+30	μΑ

Notes 1. X1, X2, RESET, P12/ASCK2/SCK2, P20/NMI, P21/INTP0, P22/INTP1, P23/INTP2/CI, P24/INTP3, P25/INTP4/ASCK/SCK1, P26/INTP5, P27/SI0, and TEST

- **2.** P40/AD0 to P47/AD7 and P50/A8 to P57/A15
- 3. P60/A16 to P63/A19, P64/RD, P65/WR, P66/WAIT/HLDRQ, and P67/REFRQ/HLDAK
- **4.** P00 to P07
- **5.** P10 to P17
- 6. P32/SCK0/SCL and P33/SO0/SDA



DC CHARACTERISTICS (TA = -40 to +85°C, VDD = AVDD = +2.7 to 5.5 V, Vss = AVss = 0 V) (2/2)

Parameter	Symbol	Condi	tions	MIN.	TYP.	MAX.	Unit
Input leakage current	lu	$0 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}}$ For pins other than pin λ	$0 \text{ V} \le V_1 \le V_{DD}$ For pins other than pin X1 when EXTC = 0			±10	μΑ
Output leakage current	ILO	$0 \text{ V} \leq \text{Vo} \leq \text{Vdd}$				±10	μΑ
V _{DD} supply current	I _{DD1}	Operation mode	Operation mode $fxx = 32 \text{ MHz}$ $VDD = +5.0 \text{ V} \pm 10\%$			45	mA
			fxx = 16 MHz VDD = +2.7 to 3.3 V		12	25	mA
	I _{DD2}	HALT mode	fxx = 32 MHz VDD = +5.0 V±10%		13	26	mA
			fxx = 16 MHz VDD = +2.7 to 3.3 V		8	12	mA
	IDD3	IDLE mode (EXTC = 0)	fxx = 32 MHz Vdd = +5.0 V±10%			12	mA
			fxx = 16 MHz VDD = +2.7 to 3.3 V			8	mA
Pull-up resistance	RL	Vı = 0 V		15		80	kΩ



AC CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = AV_{DD} = +2.7 \text{ to } 5.5 \text{ V}$, $V_{SS} = AV_{SS} = 0 \text{ V}$)

(1) Read/write operation (1/2)

Parameter	Symbol	Cond	itions	MIN.	MAX.	Unit
Address setup time	t sast	VDD = +5.0 V±10%		(0.5+a)T-15		ns
				(0.5+a)T-31		ns
ASTB high-level width	twsтн	VDD = +5.0 V±10%		(0.5+a)T-17		ns
				(0.5+a)T-40		ns
Address hold time	t HSTLA	VDD = +5.0 V±10%		0.5T-24		ns
(from ASTB↓)				0.5T-34		ns
Address hold time (from \overline{RD} 1)	thra			0.5T-14		ns
RD↓ delay time from	t dar	VDD = +5.0 V±10%		(1+a)T-9		ns
address				(1+a)T-15		ns
Address float time (from $\overline{RD}\downarrow$)	tfra				0	ns
Data input time from	tdaid	VDD = +5.0 V±10%			(2.5+a+n)T-37	ns
address					(2.5+a+n)T-52	ns
Data input time from	tdstid	VDD = +5.0 V±10%			(2+n)T-40	ns
ASTB↓					(2+n)T-60	ns
Data input time from	tdrid	VDD = +5.0 V±10%			(1.5+n)T-50	ns
RD↓					(1.5+n)T-70	ns
$\overline{\text{RD}} \downarrow$ delay time from ASTB \downarrow	tostr			0.5T-9		ns
Data hold time (from RD↑)	thrid			0		ns
Address active time	tdra	After program is read	VDD = +5.0 V±10%	0.5T-8		ns
from RD↑				0.5T-12		ns
		After data is read	VDD = +5.0 V±10%	1.5T-8		ns
				1.5T-12		ns
ASTB \uparrow delay time from $\overline{\text{RD}}\uparrow$	tdrst			0.5T-17		ns
RD low-level width	twrl	VDD = +5.0 V±10%		(1.5+n)T-30		ns
				(1.5+n)T-40		ns
Address hold time (from \overline{WR} \uparrow)	thwa			0.5T-14		ns
WR↓ delay time from	tdaw	VDD = +5.0 V±10%		(1+a)T-5		ns
address				(1+a)T-15		ns
Data output delay time	tostod	VDD = +5.0 V±10%			0.5T+19	ns
from ASTB↓					0.5T+35	ns
Data output delay time from $\overline{\text{WR}} \downarrow$	towod				0.5T-11	ns
$\overline{\text{WR}} \downarrow$ output delay time from ASTB \downarrow	tostw			0.5T-9		ns

Remark T: TCYK (system clock cycle time)

a: 1 (during address wait), otherwise, 0

n: Number of wait states ($n \ge 0$)



(1) Read/write operation (2/2)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Data setup time (to WR↑)	tsodw	VDD = +5.0 V±10%	(1.5+n)T-30		ns
			(1.5+n)T-40		ns
Data hold time	thwod	VDD = +5.0 V±10%	0.5T-5		ns
(from WR↑) Note			0.5T-25		ns
ASTB↑ delay time (from WR↑)	towst		0.5T-12		ns
WR low-level width	twwL	VDD = +5.0 V±10%	(1.5+n)T-30		ns
			(1.5+n)T-40		ns

Note The hold time includes the time during which V_{OH1} and V_{OL1} are held under the load conditions of $C_L = 50$ pF and $R_L = 4.7$ k Ω .

Remark T: Tcyk (system clock cycle time)

n: Number of wait states $(n \ge 0)$

(2) Bus hold timing

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Float delay time from HLDRQ↑	trhqc			(6+a+n)T+50	ns
HLDAK↑ delay time	t DHQHHAH	VDD = +5.0 V±10%		(7+a+n)T+30	ns
from HLDRQ↑				(7+a+n)T+40	ns
HLDAK↑ delay time from float	tdcfha			1T+30	ns
HLDAK↓ delay time	t DHQLHAL	VDD = +5.0 V±10%		2T+40	ns
from HLDRQ↓				2T+60	ns
Active delay time from	t DHAC	VDD = +5.0 V±10%	1T-20		ns
HLDAK↓			1T-30		ns

Remark T: TCYK (system clock cycle time)

a: 1 (during address wait), otherwise, 0

n: Number of wait states ($n \ge 0$)



(3) External wait timing

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
WAIT↓ input time from	t DAWT	V _{DD} = +5.0 V±10%		(2+a)T-40	ns
address				(2+a)T-60	ns
WAIT↓ input time from	tostwt	$V_{DD} = +5.0 V \pm 10\%$		1.5T-40	ns
ASTB↓				1.5T-60	ns
WAIT hold time from	tнsтwтн	$V_{DD} = +5.0 V \pm 10\%$	(0.5+n)T+5		ns
ASTB↓			(0.5+n)T+10		ns
WAIT↑ delay time from	tostwth	$V_{DD} = +5.0 V \pm 10\%$		(1.5+n)T-40	ns
ASTB↓				(1.5+n)T-60	ns
WAIT↓ input time from	tdrwtl	$V_{DD} = +5.0 V \pm 10\%$		T-50	ns
RD↓				T-70	ns
WAIT↓ hold time from	thrwt	$V_{DD} = +5.0 V \pm 10\%$	nT+5		ns
RD↓			nT+10		ns
WAIT↑ delay time from	tdrwth	V _{DD} = +5.0 V±10%		(1+n)T-40	ns
RD↓				(1+n)T-60	ns
Data input time from	towtid	$V_{DD} = +5.0 V \pm 10\%$		0.5T-5	ns
WAIT↑				0.5T-10	ns
WR↑ delay time from WAIT↑	towtw		0.5T		ns
RD↑ delay time from WAIT↑	towtr		0.5T		ns
WAIT↓ input time from	towwtl	V _{DD} = +5.0 V±10%		T-5	ns
WR↓				T-75	ns
WAIT hold time from	thwwt	V _{DD} = +5.0 V±10%	nT+5		ns
WR↓			nT+10		ns
WAIT↑ delay time from	towwth	V _{DD} = +5.0 V±10%		(1+n)T-40	ns
WR↓				(1+n)T-70	ns

Remark T: Tcyk (system clock cycle time)

a: 1 (during address wait), otherwise, 0

n: Number of wait states $(n \ge 0)$

(4) Refresh timing

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Random read/write cycle time	trc		3T		ns
REFRQ low-level pulse	twrfql	VDD = +5.0 V±10%	1.5T-25		ns
width			1.5T-30		ns
REFRQ delay time from ASTB↓	tdstrfq		0.5T–9		ns
REFRQ delay time from RD↑	tdrrfq		1.5T–9		ns
REFRQ delay time from WR↑	towrfq		1.5T-9		ns
ASTB delay time from REFRQ↑	tdrfqst		0.5T-15		ns
REFRQ high-level pulse	twrfqh	VDD = +5.0 V±10%	1.5T-25		ns
width			1.5T-30		ns

Remark T: Tcyk (system clock cycle time)



SERIAL OPERATION (TA = -40 to +85°C, VDD = +2.7 to 5.5 V, AVss = Vss = 0 V)

(1) CSI

Parameter	Symbol		Conditions	MIN.	MAX.	Unit
Serial clock cycle time (SCK0)	tcysko	Input	External clock When SCK0 and SO0 are CMOS I/O	10/fxx+380		ns
		Output		Т		μs
Serial clock low-level width (SCK0)	twsklo	Input	External clock When SCK0 and SO0 are CMOS I/O	5/fxx+150		ns
		Output		0.5T-40		μs
Serial clock high-level width (SCK0)	twskH0	Input	External clock When SCK0 and SO0 are CMOS I/O	5/fxx+150		ns
		Output		0.5T-40		μs
SI0 setup time (to SCK0↑)	tsssko			40		ns
SI0 hold time (from SCK0↑)	thssk0			5/fxx+40		ns
SO0 output delay time (from SCK0↓)	tdsbsk1	CMOS push-pull output (3-wire serial I/O mode)		0	5/fxx+150	ns
	tosbsk2	Open-drain (2-wire seri	output al I/O mode), RL = 1 k Ω	0	5/fxx+400	ns

Remarks 1. The values in this table are those when C_L is 100 pF.

2. T: Serial clock cycle set by software. The minimum value is 16/fxx.

3. fxx: Oscillation frequency

(2) I²C

Parameter	Symbol	Standard mode I ² C bus fxx = 4 to 32 MHz			High-speed mode I^2C bus $fxx = 8$ to 32 MHz		
		MIN.	MAX.	MIN.	MAX.		
SCL clock frequency	fscL	0	100	0	400	kHz	
Hold time of SCL clock low-level state	tLOW	4.7		1.3		μs	
Hold time of SCL clock high-level state	tніgн	4.0		0.6		μs	
Data hold time	thd; DAT	300		300	900	ns	
Data setup time	tsu; DAT	250		100		ns	
Rising time of SDA and SCL signals	tr		1000	20+0.1Cb	300	ns	
Falling time of SDA and SCL signals	tr		300	20+0.1Cb	300	ns	
Load capacitance of each bus line	Cb		400		400	pF	



(3) IOE1, IOE2

Parameter	Symbol		Conditions	MIN.	MAX.	Unit
Serial clock cycle time (SCK1, SCK2)	tcysk1	Input	V _{DD} = +5.0 V±10%	250 500		ns
(SCR1, SCR2)		Output	Internal clock divided by 16	T		ns
Serial clock low-level	twskl1	Input	VDD = +5.0 V±10%	85		ns
width ($\overline{SCK1}$, $\overline{SCK2}$)				210		ns
		Output	Internal clock divided by 16	0.5T-40		ns
Serial clock high-level	twskH1	Input	$V_{DD} = +5.0 V \pm 10\%$	85		ns
width ($\overline{SCK1}$, $\overline{SCK2}$)				210		ns
		Output	Internal clock divided by 16	0.5T-40		ns
SI1, SI2 setup time (to SCK1, SCK2↑)	tsssk1			40		ns
SI1, SI2 hold time (from SCK1, SCK2↑)	thssk1			40		ns
SO1, SO2 output delay time (from SCK1, SCK2↓)	tososk			0	50	ns
SO1, SO2 output hold time (from SCK1, SCK2 ↑)	thsosk	During da	ta transfer	0.5tcysk1-40		ns

Remarks 1. The values in this table are those when C_L is 100 pF.

2. T: Serial clock cycle set by software. The minimum value is 16/fxx.

(4) UART, UART2

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASCK clock input cycle	tcyask	VDD = +5.0 V±10%	125		ns
time			250		ns
ASCK clock low-level	twaskl	$V_{DD} = +5.0 \text{ V} \pm 10\%$	52.5		ns
width			85		ns
ASCK clock high-level	twaskh	$V_{DD} = +5.0 \text{ V} \pm 10\%$	52.5		ns
width			85		ns



CLOCK OUTPUT OPERATION

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
CLKOUT cycle time	tcycL		nT		ns
CLKOUT low-level width	tcll	VDD = +5.0 V±10%	0.5tcycL-10		ns
			0.5tcycL-20		ns
CLKOUT high-level width	tclh	VDD = +5.0 V±10%	0.5tcycL-10		ns
			0.5tcycL-20		ns
CLKOUT rising time	tclr	VDD = +5.0 V±10%		10	ns
				20	ns
CLKOUT falling time	tclf	VDD = +5.0 V±10%		10	ns
				20	ns

Remark n: Divided frequency ratio set by software in the CPU (n = 1, 2, 4, 8, 16)

T: tcyk (system clock cycle time)

OTHER OPERATIONS

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
NMI low-level width	twnil		10		μs
NMI high-level width	twnih		10		μs
INTP0 low-level width	twitol		3tcysmp+10		ns
INTP0 high-level width	twiтон		3tcysmp+10		ns
INTP1 to INTP3, CI low-level width	twiT1L		3tсүсри+10		ns
INTP1 to INTP3, CI high-level width	twiT1H		Зтсусри+10		ns
INTP4, INTP5 low-level width	twit2L		10		μs
INTP4, INTP5 high-level width	twit2H		10		μs
RESET low-level width	twrsl		10		μs
RESET high-level width	twrsh		10		μs

Remark tcysmp: Sampling clock set by software

 $\ensuremath{\mathsf{tcycPU}}\xspace$ CPU operation clock set by software in the CPU



A/D CONVERTER CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = AV_{DD} = AV_{REF1} = +2.7 \text{ to } 5.5 \text{ V}$, $V_{SS} = AV_{SS} = 0 \text{ V}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution			8			bit
Total error Note					1.0	%
Linearity calibration Note					0.8	%
Quantization error					±1/2	LSB
Conversion time	tconv	FR = 1	120			tcyk
		FR = 0	180			tcyk
Sampling time	tsamp	FR = 1	24			tcyk
		FR = 0	36			tcyk
Analog input voltage	VIAN		-0.3		AVREF1+0.3	V
Analog input impedance	RAN			1000		$M\Omega$
AVREF1 current	Alref1			0.5	1.5	mA
AVDD supply current	Aldd1	fxx = 32 MHz, CS = 1		2.0	5.0	mA
	AIDD2	STOP mode, CS = 0		1.0	20	μΑ

Note Quantization error is not included. This parameter is indicated as the ratio to the full-scale value.

Remark tcyk: System clock cycle time



D/A CONVERTER CHARACTERISTICS (TA = -40 to +85°C, VDD = AVDD = +2.7 to 5.5 V, Vss = AVss = 0 V)

Parameter	Symbol	Cone	ditions	MIN.	TYP.	MAX.	Unit
Resolution				8			bit
Total error		Load conditions: 4 M Ω , 30 pF	VDD = AVDD = AVREF2 = +2.7 to 5.5 V AVREF3 = 0 V			0.6	%
			VDD = AVDD = +2.7 to 5.5 V AVREF2 = 0.75VDD AVREF3 = 0.25VDD			0.8	%
		Load conditions: 2 MΩ, 30 pF	VDD = AVDD = AVREF2 = +2.7 to 5.5 V AVREF3 = 0 V			0.8	%
			VDD = AVDD = +2.7 to 5.5 V AVREF2 = 0.75VDD AVREF3 = 0.25VDD			1.0	%
Settling time		Load conditions: 2 MΩ	, 30 pF			10	μs
Output resistance	Ro	DACS0, 1 = 55 H			10		kΩ
Analog reference voltage	AV _{REF2}			0.75V _{DD}		VDD	V
	AV _{REF3}			0		0.25V _{DD}	V
AVREF2, AVREF3 resistance	RAIREF	DACS0, 1 = 55 H		4	8		kΩ
Reference power supply	Alref2			0		5	mA
input current	Alref3			-5		0	mA



DATA RETENTION CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention voltage	VDDDR	STOP mode	2.5		5.5	V
Data retention current	Idddr	VDDDR = +2.7 to 5.5 V		10	50	μΑ
		VDDDR = +2.5 V		2	10	μΑ
V _{DD} rising time	trvd		200			μs
V _{DD} falling time	trvd		200			μs
V _{DD} hold time (from STOP mode setting)	thvd		0			ms
STOP release signal input time	tdrel		0			ms
Oscillation stabilization	twait	Crystal resonator	30			ms
wait time		Ceramic resonator	5			ms
Low-level input voltage	VIL	Specific pins Note	0		0.1Vdddr	V
High-level input voltage	VIH		0.9Vdddr	-	VDDDR	V

Note RESET, P20/NMI, P21/INTP0, P22/INTP1, P23/INTP2/CI, P24/INTP3, P25/INTP4/ASCK/SCK1, P26/INTP5, P27/SI0, P32/SCK0/SCL, and P33/SO0/SDA pins

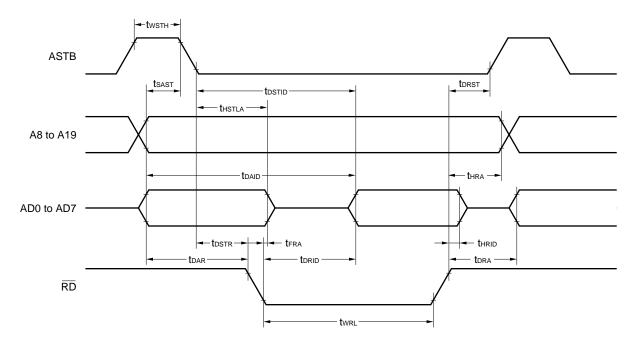
AC TIMING TEST POINTS



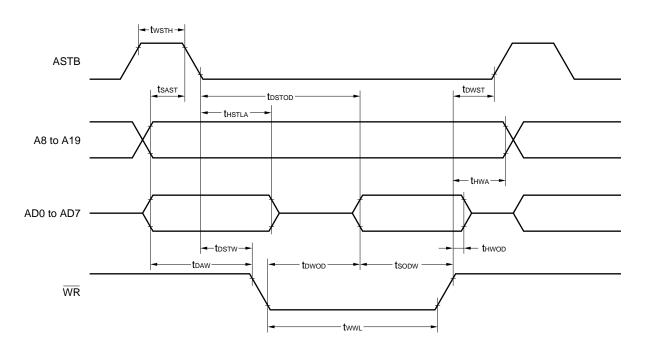


TIMING WAVEFORM

(1) Read operation

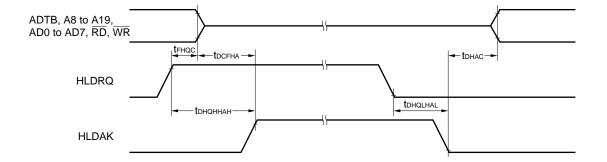


(2) Write operation



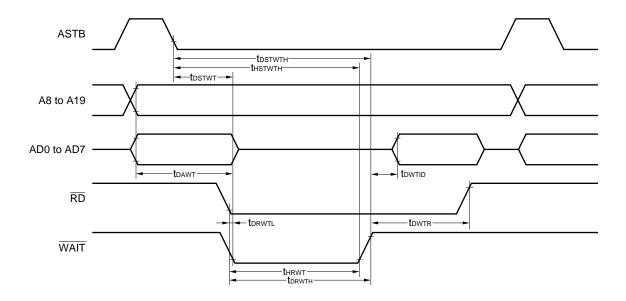


HOLD TIMING

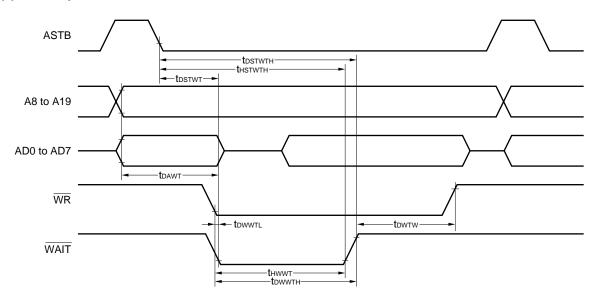


EXTERNAL WAIT SIGNAL INPUT TIMING

(1) Read operation



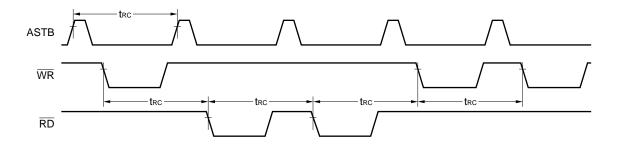
(2) Write operation



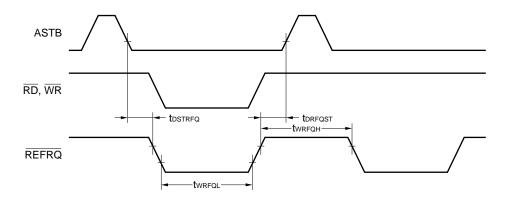


REFRESH TIMING WAVEFORM

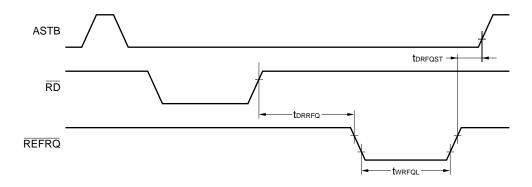
(1) Random read/write cycle



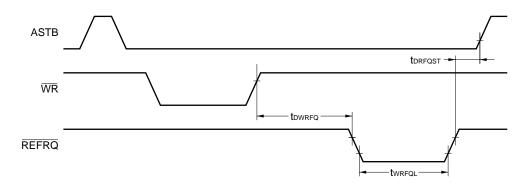
(2) When refresh memory is accessed for read and write at the same time



(3) Refresh after read



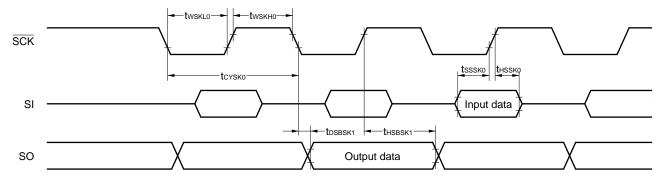
(4) Refresh after write



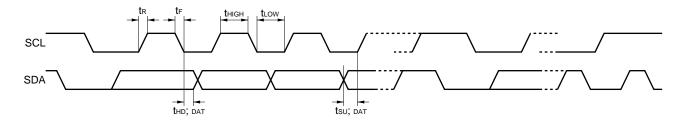


SERIAL OPERATION

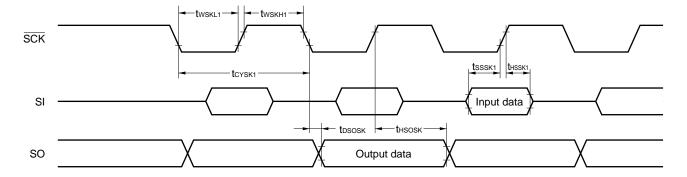
(1) CSI



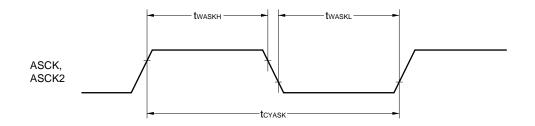
(2) I²C



(3) IOE1, IOE2

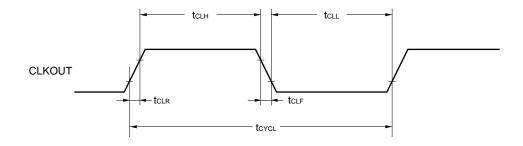


(4) UART, UART2

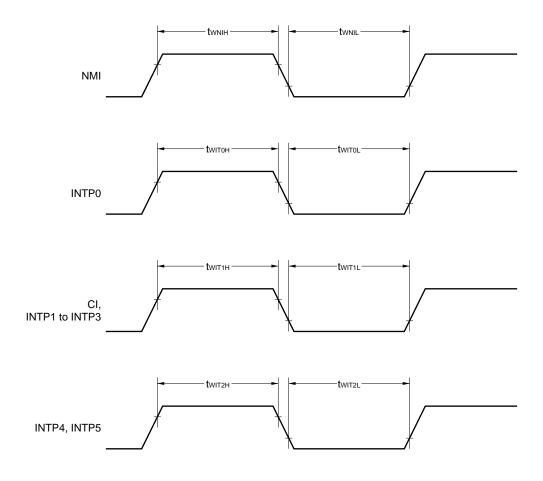




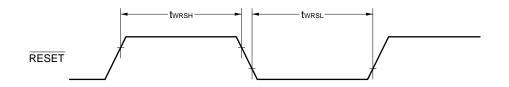
CLOCK OUTPUT TIMING



INTERRUPT INPUT TIMING

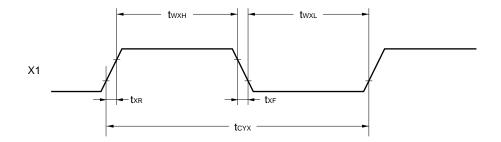


RESET INPUT TIMING

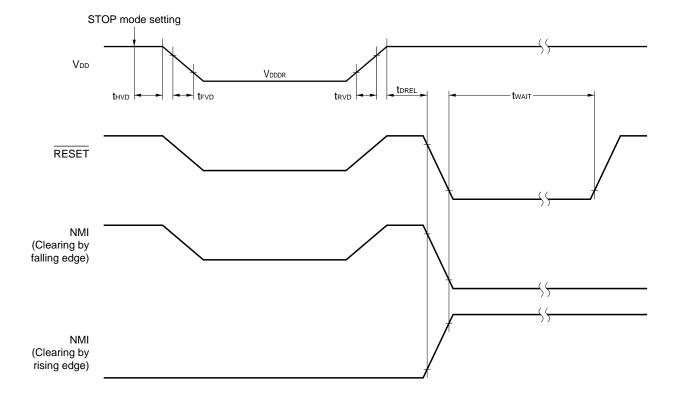




EXTERNAL CLOCK TIMING

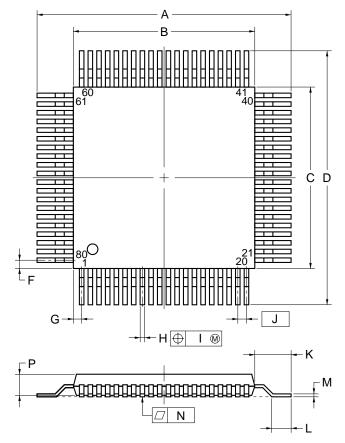


DATA RETENTION CHARACTERISTICS

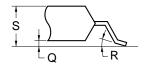


14. PACKAGE DRAWINGS

80 PIN PLASTIC QFP (14×14)



detail of lead end



NOTE

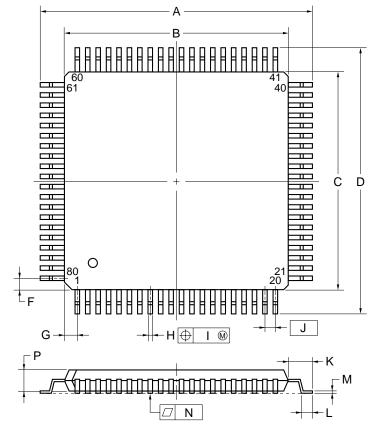
Each lead centerline is located within 0.13 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
Α	17.2±0.4	0.677±0.016
В	14.0±0.2	$0.551^{+0.009}_{-0.008}$
С	14.0±0.2	$0.551^{+0.009}_{-0.008}$
D	17.2±0.4	0.677±0.016
F	0.825	0.032
G	0.825	0.032
Н	0.30±0.10	$0.012^{+0.004}_{-0.005}$
I	0.13	0.005
J	0.65 (T.P.)	0.026 (T.P.)
K	1.6±0.2	0.063±0.008
L	0.8±0.2	$0.031^{+0.009}_{-0.008}$
М	$0.15^{+0.10}_{-0.05}$	$0.006^{+0.004}_{-0.003}$
N	0.10	0.004
Р	2.7	0.106
Q	0.1±0.1	0.004±0.004
R	5°±5°	5°±5°
s	3.0 MAX.	0.119 MAX.

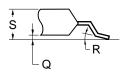
S80GC-65-3B9-4

Remark The shape and material of the ES version are the same as those of the corresponding mass-produced product.

★ 80 PIN PLASTIC QFP (14×14)



detail of lead end



NOTE

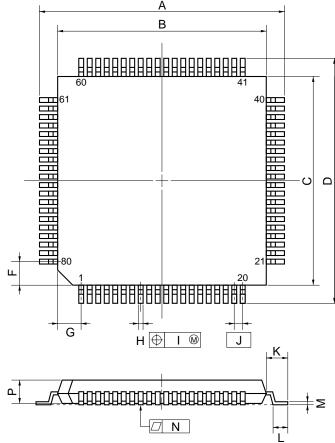
Each lead centerline is located within 0.13 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
Α	17.20±0.20	0.677±0.008
В	14.00±0.20	$0.551^{+0.009}_{-0.008}$
С	14.00±0.20	$0.551^{+0.009}_{-0.008}$
D	17.20±0.20	0.677±0.008
F	0.825	0.032
G	0.825	0.032
Н	0.32±0.06	$0.013^{+0.002}_{-0.003}$
I	0.13	0.005
J	0.65 (T.P.)	0.026 (T.P.)
K	1.60±0.20	0.063±0.008
L	0.80±0.20	0.031+0.009
М	0.17+0.03	0.007+0.001
N	0.10	0.004
Р	1.40±0.10	0.055±0.004
Q	0.125±0.075	0.005±0.003
R	3°+7°	3°+7° -3°
S	1.70 MAX.	0.067 MAX.

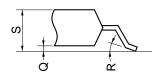
P80GC-65-8BT

Remark The shape and material of the ES version are the same as those of the corresponding mass-produced product.

80 PIN PLASTIC TQFP (FINE PITCH) (\Box 12)



detail of lead end



NOTE

Each lead centerline is located within 0.10 mm (0.004 inch) of its true position (T.P.) at maximum material condition.

MILLIMETERS	INCHES
14.0±0.2	$0.551^{+0.009}_{-0.008}$
12.0±0.2	$0.472^{+0.009}_{-0.008}$
12.0±0.2	0.472+0.009
14.0±0.2	0.551+0.009
1.25	0.049
1.25	0.049
0.22+0.05	0.009±0.002
0.10	0.004
0.5 (T.P.)	0.020 (T.P.)
1.0±0.2	$0.039^{+0.009}_{-0.008}$
0.5±0.2	0.020+0.008
0.145 ^{+0.055} _{-0.045}	0.006±0.002
0.10	0.004
1.05	0.041
0.05±0.05	0.002±0.002
5°±5°	5°±5°
1.27 MAX.	0.050 MAX.
	14.0±0.2 12.0±0.2 12.0±0.2 14.0±0.2 1.25 1.25 0.22 ^{+0.05} 0.10 0.5 (T.P.) 1.0±0.2 0.145 ^{+0.055} 0.10 1.05 0.05±0.05 5°±5°

P80GK-50-BE9-4

Remark The shape and material of the ES version are the same as those of the corresponding mass-produced product.



★ 15. RECOMMENDED SOLDERING CONDITIONS

It is recommended that the μ PD784035Y, 784036Y, 784037Y, and 784038Y be soldered under the following conditions.

For details on the recommended soldering conditions, refer to information document "Semiconductor Device Mounting Technology Manual" (C10535E).

For soldering methods and conditions other than those recommended, please consult an NEC representative.

Caution The soldering conditions for the μ PD784035YGK- $\times\times$ -BE9 and 784036YGK- $\times\times$ -BE9 are undefined because these products are currently under development.

Table 15-1. Soldering Conditions for Surface Mount Type (1/2)

```
(1) \muPD784035YGC-\times\times-3B9: 80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick) \muPD784036YGC-\times\times-3B9: 80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick) \muPD784037YGC-\times\times-3B9: 80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick) \muPD784038YGC-\times\times-3B9: 80-pin plastic QFP (14 \times 14 mm, 2.7-mm thick)
```

Soldering Method	Soldering Conditions	Recommended
		Condition Symbol
Infrared ray reflow	Package peak temperature: 235°C, Reflow time: 30 seconds or less (210°C or more) Number of reflow processes: 3 or less	IR35-00-3
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or less (200°C or more) Number of reflow processes: 3 or less	VP15-00-3
Wave soldering	Solder bath temperature: 260°C or less, Flow time: 10 seconds or less, Number of flow processes: 1, Preheating temperature: 120°C max. (package surface temperature)	WS60-00-1
Partial heating	Pin temperature: 300°C or less, Flow time: 3 seconds or less (for one side of the a device)	_

Caution Do not apply two or more different soldering methods to one chip (except for partial heating method).

```
(2) \muPD784035YGC-\times\times\times-8BT: 80-pin plastic QFP (14 \times 14 mm, 1.4-mm thick) \muPD784036YGC-\times\times\times-8BT: 80-pin plastic QFP (14 \times 14 mm, 1.4-mm thick) \muPD784037YGC-\times\times\times-8BT: 80-pin plastic QFP (14 \times 14 mm, 1.4-mm thick) \muPD784038YGC-\times\times\times-8BT: 80-pin plastic QFP (14 \times 14 mm, 1.4-mm thick)
```

Soldering Method	Soldering Conditions	Recommended
		Condition Symbol
Infrared ray reflow	Package peak temperature: 235°C, Reflow time: 30 seconds or less (210°C or more) Number of reflow processes: 2 or less	IR35-00-2
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or less (200°C or more) Number of reflow processes: 2 or less	VP15-00-2
Wave soldering	Solder bath temperature: 260°C or less, Flow time: 10 seconds or less, Number of flow processes: 1, Preheating temperature: 120°C max. (package surface temperature)	WS60-00-1
Partial heating	Pin temperature: 300°C or less, Flow time: 3 seconds or less (for one side of the a device)	_

Caution Do not apply two or more different soldering methods to one chip (except for partial heating method).

Table 15-1. Soldering Conditions for Surface Mount Type (2/2)

(3) μ PD784037YGK- $\times\times$ -BE9: 80-pin plastic TQFP (fine-pitch) (12 \times 12 mm) μ PD784038YGK- $\times\times$ -BE9: 80-pin plastic TQFP (fine-pitch) (12 \times 12 mm)

Soldering Method	Soldering Conditions	Recommended
		Condition Symbol
Infrared ray reflow	Package peak temperature: 235°C, Reflow time: 30 seconds or less (210°C or more) Number of reflow processes: 2 or less Exposure limit: 7 days ^{Note} (10 hours of pre-baking is required at 125°C afterward)	IR35-107-2
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or less (200°C or more) Number of reflow processes: 2 or less Exposure limit: 7 days ^{Note} (10 hours of pre-baking is required at 125°C afterward)	VP15-107-2
Partial heating	Pin temperature: 300°C or less, Flow time: 3 seconds or less (per side of a device)	_

Note Maximum number of days during which the product can be stored at a temperature of 25°C and a relative humidity of 65% or less after dry-pack package is opened.

Caution Do not apply two or more different soldering methods to one chip (except for partial heating method).



APPENDIX A DEVELOPMENT TOOLS

The following development tools are available for supporting development of a system using the μ PD784038Y.

Language processor software

RA78K4 ^{Note 1}	Assembler package common to 78K/IV Series
CC78K4Note 1	C compiler package common to 78K/IV Series
CC78K4-LNote 1	C compiler library source file common to 78K/IV Series

PROM writing tool

PG-1500	PROM program writer
PA-78P4026GC	Programmer adapter connected to PG-1500
PA-78P4038GK	
PA-78P4026KK	
PG-1500 controllerNote 2	PG-1500 control program

Debugging tool

IE-784000-R	In-circuit emulator common to 78K/IV Series
IE-784000-R-BK	Break board common to 78K/IV Series
IE-784038-R-EM1	Emulation board for evaluation of μ PD784038Y Subseries
IE-784000-R-EM	
IE-70000-98-IF-B	Interface adapter when PC-9800 series (except notebook type) is used as host
	machine
IE-70000-98N-IF	Interface adapter and cable when notebook type PC-9800 series is used as host
	machine
IE-70000-PC-IF-B	Interface adapter when IBM PC/AT™ is used as host machine
IE-78000-R-SV3	Interface adapter and cable when EWS is used as host machine
EP-78230GC-R	Emulation probe for 80-pin plastic QFP (GC-3B9, GC-8BT type) common to μ PD784038Y
	Subseries
EP-78054GK-R	Emulation probe for 80-pin plastic TQFP (fine pitch) (GK-BE9 type) common to
	μ PD784038Y Subseries
EV-9200GC-80	Socket mounted on board of target system created for 80-pin plastic QFP (GC-3B9,
	GC-8BT type)
TGK-080SDW	Adapter mounted on board of target system created for 80-pin plastic TQFP (fine
	pitch) (GK-BE9)
EV-9900	Jig used to remove μPD78P4038YKK-T from EV-9200GC-80
SM78K4 ^{Note 3}	System simulator common to 78K/IV Series
ID78K4 ^{Note 3}	Integrated debugger for IE-784000-R
DF784038Note 4	Device file for μPD784038Y Subseries

Real-time OS

RX78K/IV ^{Note 4}	Real-time OS for 78K/IV Series
MX78K4Note 2	OS for 78K/IV Series

- Notes. 1. PC-9800 series (MS-DOSTM) base
 - IBM PC/AT and compatible machine (PC DOS™, Windows™, MS-DOS, IBM DOS™) base
 - HP9000 series 700[™] (HP-UX[™]) base
 - SPARCstation[™] (SunOS[™]) base
 - NEWSTM (NEWS-OSTM) base
 - 2. PC-9800 series (MS-DOS) base
 - IMB PC/AT and compatible machine (PC DOS, Windows, MS-DOS, IBM DOS) base
 - 3. PC-9800 series (MS-DOS+Windows) base
 - IBM PC/AT and compatible machine (PC DOS, Windows, MS-DOS, IBM DOS) base
 - · HP9000 series 700 (HP-UX) base
 - · SPARCstation (SunOS) base
 - 4. PC-9800 series (MS-DOS) base
 - IBM PC/AT and compatible machine (PC DOS, Windows, MS-DOS, IBM DOS) base
 - · HP9000 series 700 (HP-UX) base
 - · SPARCstation (SunOS) base
- Remarks 1. RA78K4, CC78K4, SM78K4, and ID78K4 are used in combination with DF784038.
 - **2.** The TGK-080SDW is a product of TOKYO ELETECH CORPORATION (Tokyo, 03-5295-1661). Consult an NEC sales representative about purchasing.



APPENDIX B RELATED DOCUMENTS

Documents related to device

Document Name	Document No.	
	Japanese	English
μPD784031Y Data Sheet	U11504J	U11504E
μPD784035Y, 784036Y, 784037Y, 784038Y Data Sheet	U10741J	This manual
μPD78P4038Y Data Sheet	U10742J	U10742E
μPD784038, 784038Y Subseries User's Manual - Hardware	U11316J	U11316J
μPD784038Y Subseries Special Function Register Table	U11091J	_
78K/IV Series User's Manual - Instructions	U10905J	U10905E
78K/IV Series Instruction Table	U10594J	_
78K/IV Series Instruction Set	U10595J	_
78K/IV Series Application Note - Software Basics	U10095J	U10095E

Documents related to development tools (User's Manuals)

Document Name		Document No.	
		Japanese	English
RA78K4 Assembler Package	Operation	U11334J	U11334E
	Language	U11162J	_
RA78K Series Structured Assembler Preprocessor		EEU-817	EEU-1402
CC78K4 Series	Operation	EEU-960	_
	Language	EEU-961	_
CC78K Series Library Source File		U12322J	_
PG-1500 PROM Programmer		U11940J	EEU-1335
PG-1500 Controller - PC-9800 Series (MS-DOS) Based		EEU-704	EEU-1291
PG-1500 Controller - IBM PC Series (PC DOS) Based		EEU-5008	U10540E
IE-784000-R		EEU-5004	EEU-1534
IE-784038-R-EM1		U11383J	U11383E
EP-78230		EEU-985	EEU-1515
EP-78054GK-R		EEU-932	EEU-1468
SM78K4 System Simulator - Windows Based	Reference	U10093J	U10093E
SM78K Series System Simulator	External component	U10092J	U10092E
	user open interface		
	specification		
ID78K4 Integrated Debugger - Windows Based	Reference	U10440J	U10440E
ID78K4 Integrated Debugger HP9000 Series 700	Reference	U11960J	Under preparation
(HP-UX) Based			

Caution The contents of the above related documents are subject to change without notice. Be sure to use the latest edition of a document for designing.



Documents related to embedded software (User's Manual)

Document Name		Document No.	
		Japanese	English
78K/IV Series Real-Time OS	Basics	U10603J	U10603E
	Installation	U10604J	U10604E
	Debugger	U10364J	_
78K/IV Series OS MX78K4	Basics	U11779J	_

Other documents

Document Name	Document No.	
	Japanese	English
IC Package Manual	C10943X	
Semiconductor Device Mounting Technology Manual	C10535J	C10535E
Quality Grades on NEC Semiconductor Devices	C11531J	C11531E
NEC Semiconductor Device Reliability/Quality Control System	C10983J	C10983E
Electrostatic Discharge (ESD) Test	MEM-539	_
Guide to Quality Assurance for Semiconductor Devices	C11893J	MEI-1202
Guide to Microcontroller-Related Products by Third Parties	U11416J	_

Caution The contents of the above related documents are subject to change without notice. Be sure to use the latest edition of a document for designing.

NOTES FOR CMOS DEVICES -

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS device behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

③ STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.



Regional Information

Some information contained in this document may vary from country to country. Before using any NEC product in your application, please contact the NEC office in your country to obtain a list of authorized representatives and distributors. They will verify:

- Device availability
- · Ordering information
- · Product release schedule
- · Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- Network requirements

In addition, trademarks, registered trademarks, export restrictions, and other legal issues may also vary from country to country.

NEC Electronics Inc. (U.S.)

Santa Clara, California Tel: 800-366-9782 Fax: 800-729-9288

NEC Electronics (Germany) GmbH

Duesseldorf, Germany Tel: 0211-65 03 02 Fax: 0211-65 03 490

NEC Electronics (UK) Ltd.

Milton Keynes, UK Tel: 01908-691-133 Fax: 01908-670-290

NEC Electronics Italiana s.r.1.

Milano, Italy Tel: 02-66 75 41 Fax: 02-66 75 42 99

NEC Electronics (Germany) GmbH

Benelux Office Eindhoven, The Netherlands Tel: 040-2445845 Fax: 040-2444580

NEC Electronics (France) S.A.

Velizy-Villacoublay, France Tel: 01-30-67 58 00 Fax: 01-30-67 58 99

NEC Electronics (France) S.A.

Spain Office Madrid, Spain Tel: 01-504-2787 Fax: 01-504-2860

NEC Electronics (Germany) GmbH

Scandinavia Office Taeby, Sweden Tel: 08-63 80 820 Fax: 08-63 80 388

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Hong Kong Tel: 2886-9318 Fax: 2886-9022/9044

NEC Electronics Hong Kong Ltd.

Seoul Branch Seoul, Korea Tel: 02-528-0303 Fax: 02-528-4411

NEC Electronics Singapore Pte. Ltd.

United Square, Singapore 1130

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